

=> fil reg

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STRUCTURE FILE UPDATES: 1 MAR 2010 HIGHEST RN 1207596-35-7
 DICTIONARY FILE UPDATES: 1 MAR 2010 HIGHEST RN 1207596-35-7

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TSCA INFORMATION NOW CURRENT THROUGH June 26, 2009.

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REGISTRY includes numerically searchable data for experimental and
 predicted properties as well as tags indicating availability of
 experimental property data in the original document. For information
 on property searching in REGISTRY, refer to:

<http://www.cas.org/support/stngen/stdoc/properties.html>

=> d que

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L2          20 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  (1333-74-0/BI OR
              15318-08-8/BI OR 19553-62-9/BI OR 20791-15-5/BI OR
              310888-77-8/BI OR 310888-80-3/BI OR 310888-81-4/BI OR
              310888-82-5/BI OR 310888-85-8/BI OR 310888-87-0/BI OR
              7358-26-1/BI OR 7440-37-1/BI OR 7440-59-7/BI OR 75-24-1/BI
              OR 7727-37-9/BI OR 870126-56-0/BI OR 870126-57-1/BI OR
              870126-58-2/BI OR 870126-59-3/BI OR 97-93-8/BI)
L3          1 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  8-HYDROXYQUINOLIN
              ATE/CN
L4          1 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  8-HYDROXYQUINOLIN
              E/CN
L5          685 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  148-24-3/CRN
L6          7 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  L5 AND (AL OR GA
              OR ZN)/ELS
L7          16 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  L2 AND M/ELS
L8          663827 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  (AL OR GA OR
              ZN)/ELS
L9          122525 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  L8 AND  CCS/CI
L10         541302 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  L8 NOT L9
L11         541302 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  L10 OR L10
L12         300000 SEA FILE=REGISTRY RAN=(173351-91-2) SPE=ON  ABB=ON  PLU=ON
              L10 OR L10
L13         241302 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  L11 NOT L12
L14         23243 SEA FILE=HCAPLUS SPE=ON  ABB=ON  PLU=ON  L7
L15         143187 SEA FILE=HCAPLUS SPE=ON  ABB=ON  PLU=ON  L9
L16         140299 SEA FILE=HCAPLUS SPE=ON  ABB=ON  PLU=ON  L12
L17         2254991 SEA FILE=HCAPLUS SPE=ON  ABB=ON  PLU=ON  L13
L18         33 SEA FILE=REGISTRY SPE=ON  ABB=ON  PLU=ON  L8 AND HYDROXYQUI
              NOL?
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 L23 1836 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L5
 L24 9 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L19
 L25 6 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L6
 L26 9679 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L18
 L27 1 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L20
 L28 11763 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON (L14 OR L15 OR
 L16 OR L17) AND (L21 OR L22 OR L23 OR L24 OR L25 OR L26 OR
 L27)
 L29 QUE SPE=ON ABB=ON PLU=ON LUM!N? OR ELECTROLUM!N? OR O
 RGANOLUM!N? OR (ELECTRO OR ORGANO OR ORG#) (2A) LUM!N? OR L
 IGH? (2A) (EMIT? OR EMISSION?) OR EL OR E(W)L OR L(W)E(W)D
 OR OLED OR LED
 L30 8689 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L28 AND L29
 L31 2171 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L30 AND PROC/RL
 L32 246823 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON "VAPOR DEPOSITION
 PROCESS"+PFT,NT/CT
 L33 251 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L31 AND L32
 L34 12 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L33 AND (L21 OR
 L22 OR L23)
 L35 414 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L30 AND (L21 OR
 L22 OR L23)
 L36 89 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L35 AND L31
 L37 12 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L36 AND CPS/RL
 L38 11 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L36 AND (VAPOR
 DEPOSIT? OR VAPOUR DEPOSIT?)
 L39 23 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L34 OR (L37 OR
 L38)
 L40 QUE SPE=ON ABB=ON PLU=ON REACTOR# OR (REACTION#) (2A)
 (VESSEL# OR CHAMBER# OR TANK# OR SYSTEM# OR SPACE# OR CO
 MPARTMENT# OR RECEPTACLE# OR PORTION# OR PORT# OR ASSEMBL
 Y# OR SUB#(W)ASSEMBLY#)
 L41 1 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L36 AND L40
 L42 7 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L31 AND L40
 L43 29 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L39 OR L41 OR L42
 L44 20 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L43 AND (1840-2006
)/PRY,AY,PY
 L45 258 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L30 AND (L21 OR
 L22)
 L48 71 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L45 AND (FEED? OR
 DELIVER? OR SUPPLY? OR DISTRIBUT? OR TRANSPORT?)
 L49 58 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L48 AND OPTIC?/SC,
 SX
 L50 49 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L49 AND (1840-2006
)/PRY,AY,PY
 L53 QUE SPE=ON ABB=ON PLU=ON FILM? OR THINFILM? OR LAYER?
 OR OVERLAY? OR OVERLAID? OR LAMIN? OR LAMEL? OR (MULTILA
 YER?) OR SHEET? OR LEAF? OR FOIL? OR COAT? OR TOPCOAT? OR
 OVERCOAT? OR VENEER? OR SHEATH? OR COVER? OR ENVELOP? OR
 ENCAS? OR ENWRAP? OR OVERSPREAD?
 L55 49 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L7 AND (L21 OR
 L22 OR L23)
 L56 10 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L55 AND L29 AND
 L53
 L57 21 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L55 AND L29
 L58 21 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L56 OR L57
 L59 18 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L58 AND (1840-2006
)/PRY,AY,PY

10/594,762

L60 38 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L44 OR L59
L61 9 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON L60 AND L50
L62 38 SEA FILE=HCAPLUS SPE=ON ABB=ON PLU=ON (L60 OR L61)

=> fil hcap

FILE 'HCAPLUS' ENTERED AT 09:35:46 ON 02 MAR 2010
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FILE COVERS 1907 - 2 Mar 2010 VOL 152 ISS 10
FILE LAST UPDATED: 1 Mar 2010 (20100301/ED)
REVISED CLASS FIELDS (/NCL) LAST RELOADED: Dec 2009
USPTO MANUAL OF CLASSIFICATIONS THESAURUS ISSUE DATE: Dec 2009

HCAplus now includes complete International Patent Classification (IPC) reclassification data for the third quarter of 2009.

CAS Information Use Policies apply and are available at:

<http://www.cas.org/legal/infopolicy.html>

This file contains CAS Registry Numbers for easy and accurate substance identification.

=> d l62 1-38 ibib ed abs hitstr hitind

L62 ANSWER 1 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
ACCESSION NUMBER: 2008:379801 HCAPLUS Full-text
DOCUMENT NUMBER: 148:415641
TITLE: Transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element
INVENTOR(S): Tateishi, Tomomi
PATENT ASSIGNEE(S): Fujifilm Corporation, Japan
SOURCE: U.S. Pat. Appl. Publ., 25 pp.
CODEN: USXXCO
DOCUMENT TYPE: Patent
LANGUAGE: English
FAMILY ACC. NUM. COUNT: 1
PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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US 20080075921	A1	20080327	US 2007-902031	20070918
			<--	
JP 2008084701	A	20080410	JP 2006-263437	20060927

PRIORITY APPLN. INFO.: JP 2006-263437 A 20060927
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ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

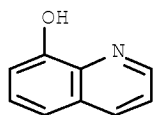
ED Entered STN: 28 Mar 2008

AB The present invention provides a transfer material with a strong adhesiveness for an electronic device that includes a transfer support and, provided on the support in this order, an insulating layer or a partition wall material layer, and a layer containing an organic low-mol.-weight compound having charge transportability; a method of forming an insulating layer and a partition wall of an electronic device using the transfer material; and a light-emitting element.

IT 148-24-3D, 8-Quinolinol, derivs. 2085-33-8, Alq3
 (transfer material for electronic device, method of forming
 insulating layer and partition wall of electronic device, and
 light-emitting element)

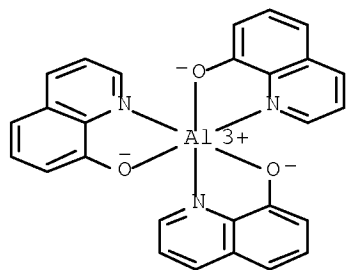
RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



INCL 428141000; 156230000; 428172000

CC 76-3 (Electric Phenomena)

Section cross-reference(s): 48, 73

ST transfer electronic device insulating layer partition wall LED
 fabrication

IT Cluster ions

(beams; transfer material for electronic device, method of forming
 insulating layer and partition wall of electronic device, and
 light-emitting element)

IT Anhydrides

(dianhydrides; transfer material for electronic device, method of
 forming insulating layer and partition wall of electronic device,
 and light-emitting element)

IT Vapor deposition process

- (ion plating; transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT Materials
(organic; transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT Chemical vapor deposition
(photochem.; transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT Polymerization
Vapor deposition process
(plasma; transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT Acrylic polymers
(polysiloxane-, US-3700; transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT Conducting polymers
(polythiophenes; transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT Chemical vapor deposition
Coating process
Dielectric films
Electroluminescent devices
Holders
Molecular beam epitaxy
Reactive sputtering
Release films
Semiconductor device fabrication
Sputtering
Transfers
(transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT Metallophthalocyanines
Polyanilines
Polyesters
Polyphenyls
(transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT Vapor deposition process
(vacuum; transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT 67-63-0, Isopropyl alcohol, processes 78-93-3, Methyl ethyl ketone, processes 108-88-3, Toluene, processes 58328-31-7 60676-86-0, Vitreous silica 475644-38-3, Optool DSX 757974-86-0, TFR-H
(transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT 50926-11-9, Indium tin oxide 128770-43-4, HP 320 (polyester)
(transfer material for electronic device, method of forming insulating layer and partition wall of electronic device, and light-emitting element)
- IT 90-44-8D, Anthrone, derivs. 92-52-4D, Biphenyl, quinone derivs.

147-14-8, Copper phthalocyanine 148-24-3D, 8-Quinolinol,
 derivs. 151-51-9D, Carbodiimide, derivs. 273-53-0D, Benzoxazole,
 metal complexes 288-42-6D, Oxazole, derivs. 288-88-0D,
 1H-1,2,4-Triazole, derivs. 486-25-9D, Fluorenone, derivs.
 574-93-6D, Phthalocyanine, derivs. 2085-33-8, Alq3
 4425-82-5D, Fluorenylidene methane, derivs. 7789-24-4, Lithium
 fluoride, processes 11120-54-0D, Oxadiazole, derivs. 12597-68-1,
 Stainless steel, processes 14990-02-4D, derivs. 25038-59-9,
 Lumirror T-60, processes 60475-00-5D, Thiopyran, derivs.
 70359-39-6D, derivs. 95270-88-5D, Polyfluorene, derivs.
 96638-49-2D, Polyphenylenevinylene, derivs. 123847-85-8
 380234-99-1, ZPN 1100 693794-98-8

(transfer material for electronic device, method of forming
 insulating layer and partition wall of electronic device, and
 light-emitting element)

OS.CITING REF COUNT: 1 THERE ARE 1 CAPLUS RECORDS THAT CITE THIS
 RECORD (1 CITINGS)

L62 ANSWER 2 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2007:1109833 HCAPLUS Full-text

DOCUMENT NUMBER: 147:416094

TITLE: Production method of organic
 electroluminescent device and electronic
 apparatus

INVENTOR(S): Takashima, Takeshi; Terao, Koichi; Shinohara,
 Takashi

PATENT ASSIGNEE(S): Seiko Epson Corp., Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 63pp.

CODEN: JKXXAF

DOCUMENT TYPE: Patent

LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
JP 2007257898	A	20071004	JP 2006-77832	20060320
			<--	
KR 2007095194	A	20070928	KR 2007-24559	20070313
			<--	
US 20070231467	A1	20071004	US 2007-688128	20070319
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PRIORITY APPLN. INFO.:			JP 2006-77832	A 20060320
			<--	

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

ED Entered STN: 04 Oct 2007

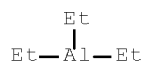
AB The invention relates to a production method of an organic electroluminescent
 device that comprises ≥ 2 electroluminescent layers having dissimilar
 luminescent colors each other and fabricated between a pair of electrodes,
 comprising the steps of: forming a 1st color electroluminescent layer on a 1st
 electrode, using an electroluminescent polymerizable compound and a carrier
 transporting polymerizable compound; irradiating the 1st color
 electroluminescent layer to cure the polymerizable compds.; and removing the
 1st color electroluminescent layer that is not irradiated.

IT 97-93-8, Triethyl aluminum, reactions 148-24-3,
 8-Quinolinol, reactions

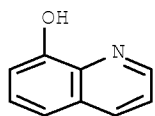
(organic electroluminescent device and electronic apparatus)

RN 97-93-8 HCAPLUS

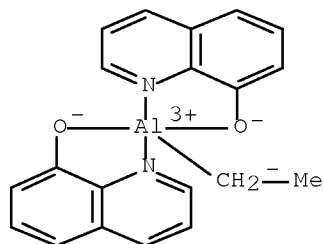
CN Aluminum, triethyl- (CA INDEX NAME)



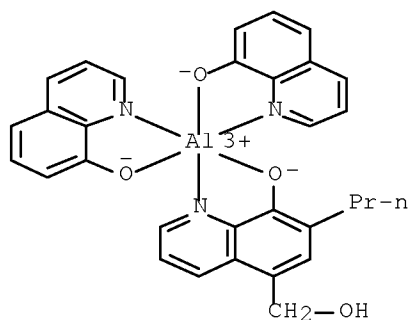
RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



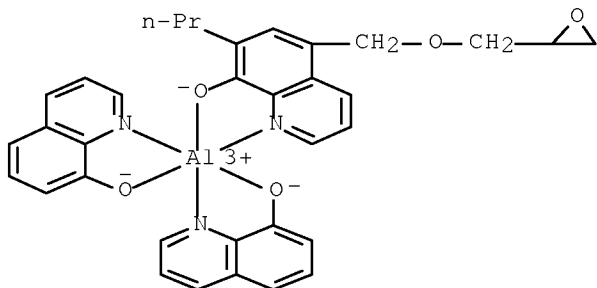
IT 950598-70-6P 950598-71-7P 950598-72-8P
 950598-73-9P
 (organic electroluminescent device and electronic apparatus)
 RN 950598-70-6 HCAPLUS
 CN Aluminum, ethylbis(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



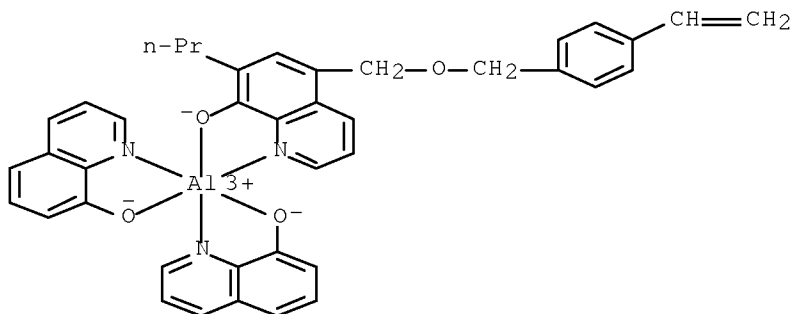
RN 950598-71-7 HCAPLUS
 CN Aluminum, [8-(hydroxy-κO)-7-propyl-5-quinolinemethanolato-κN1]bis(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



RN 950598-72-8 HCAPLUS
 CN Aluminum, [5-[(2-oxiranylmethoxy)methyl]-7-propyl-8-quinolinolato- κ N1, κ O8]bis(8-quinolinolato- κ N1, κ O8)- (CA INDEX NAME)



RN 950598-73-9 HCAPLUS
 CN Aluminum, [5-[[[4-ethenylphenyl)methoxy]methyl]-7-propyl-8-quinolinolato- κ N1, κ O8]bis(8-quinolinolato- κ N1, κ O8)- (CA INDEX NAME)



CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
 Section cross-reference(s): 25, 27, 74
 ST org electroluminescent device electronic app
 IT Electroluminescent devices
 (displays; organic electroluminescent device and electronic apparatus)
 IT luminescent screens
 (electroluminescent; organic electroluminescent device and electronic apparatus)
 IT Coating process
 Electric apparatus
 Electroluminescent devices
 (organic electroluminescent device and electronic apparatus)
 IT 64-17-5, Ethanol, reactions 97-93-8, Triethyl aluminum, reactions 98-73-7 100-39-0 100-51-6, Benzylalcohol, reactions 106-38-7 106-89-8, Epichlorohydrin, reactions 108-24-7 108-44-1,

m-Toluidine, reactions 121-43-7, Boric acid trimethyl ester
 137-07-5 148-24-3, 8-Quinolinol, reactions 302-01-2,
 Hydrazine, reactions 507-16-4, Thionyl bromide 612-62-4,
 2-Chloroquinoline 873-75-6, 4-Bromobenzylalcohol 1592-20-7,
 4-Vinylbenzylchloride 2746-25-0, 4-Methoxybenzylbromide 3001-15-8,
 4,4'-Diiodobiphenyl 3006-96-0 3047-32-3 4316-58-9 5029-67-4,
 2-Iodopyridine 5798-75-4 7719-09-7, Thionyl chloride 25574-11-2
 30525-89-4, Paraformaldehyde 58327-60-9, 7-Propyl-8-quinolinol
 59016-93-2 76283-09-5, 4-Bromo-2-fluorobenzylbromide 91251-45-5
 951123-25-4

(organic electroluminescent device and electronic apparatus)

IT 537-92-8P 1484-13-5P, N-Vinylcarbazole 1710-98-1P 14996-61-3P
 49743-87-5P 69135-05-3P 96411-61-9P 421553-47-1P 433332-03-7P
 890844-70-9P 950590-42-8P 950590-43-9P 950590-44-0P
 950590-45-1P 950590-46-2DP, reaction products with epichlorohydrin
 or 4-vinylbenzylchloride 950590-47-3P 950590-49-5P 950590-50-8P
 950590-51-9P 950590-52-0P 950590-53-1P 950590-54-2P
 950590-57-5P 950590-58-6P 950590-59-7P 950590-61-1P
 950590-62-2P 950598-61-5P 950598-62-6P 950598-63-7P
 950598-64-8P 950598-65-9P 950598-66-0P 950598-67-1P
 950598-68-2P 950598-69-3P 950598-70-6P
 950598-71-7P 950598-72-8P 950598-73-9P
 951123-28-7P 951123-29-8P 951123-30-1P 951123-31-2P

(organic electroluminescent device and electronic apparatus)

OS.CITING REF COUNT: 2 THERE ARE 2 CAPLUS RECORDS THAT CITE THIS
 RECORD (2 CITINGS)

L62 ANSWER 3 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2007:1056999 HCAPLUS Full-text
 DOCUMENT NUMBER: 147:395308
 TITLE: Method for manufacturing light

emitting element, light
 emitting device, and electronic apparatus

INVENTOR(S): Takashima, Takeshi; Terao, Koichi; Shinohara,
 Takashi

PATENT ASSIGNEE(S): Seiko Epson Corporation, Japan

SOURCE: U.S. Pat. Appl. Publ., 37pp.

CODEN: USXXCO

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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US 20070218190	A1	20070920	US 2007-688126	20070319
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JP 2007257897	A	20071004	JP 2006-77831	20060320
			<--	
KR 2007095196	A	20070928	KR 2007-24577	20070313
			<--	
PRIORITY APPLN. INFO.:			JP 2006-77831	A 20060320
			<--	

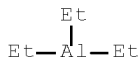
ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

ED Entered STN: 20 Sep 2007

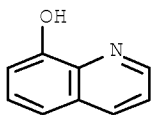
AB A method for manufacturing a light-emitting element, including: forming a film
 on one side of a first electrode; obtaining a light-emitting layer in the film
 by polymerizing a first compound as well as at least one of a second compound
 and a third compound; and installing a second electrode on a side opposite
 from the first electrode in the light-emitting layer; wherein: the first

compound is provided with an emissive light-emitting moiety and a first polymerizable group; the second compound is provided with a hole-transporting hole transport moiety and a second polymerizable group; and the third compound is provided with an electron-transporting electron transport moiety and a third polymerizable group.

IT 97-93-8, Triethylaluminum, reactions 148-24-3,
8-Quinolinol, reactions
(method for manufacturing light-emitting element,
light-emitting device, and electronic apparatus)
RN 97-93-8 HCAPLUS
CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS
CN 8-Quinolinol (CA INDEX NAME)



INCL 427066000; 427064000
CC 74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other Reprographic Processes)
ST manuf light emitting element device electronic app
IT Electroluminescent devices
(method for manufacturing light-emitting element,
light-emitting device, and electronic apparatus)
IT 97-93-8, Triethylaluminum, reactions 98-73-7,
p-t-Butylbenzoic acid 100-39-0, Benzyl bromide 106-89-8,
Epichlorohydrin, reactions 137-07-5, 2-Aminothiophenol
148-24-3, 8-Quinolinol, reactions 302-01-2, Hydrazine,
reactions 507-16-4, Thionyl bromide 612-62-4, 2-Chloroquinoline
873-75-6, 4-Bromobenzyl alcohol 1592-20-7, 4-Vinylbenzyl chloride
2156-04-9, 4-Vinylphenylboronic acid 2746-25-0, 4-Methoxybenzyl
bromide 3006-96-0, 4-Hydroxymethylbenzoic acid 3047-32-3,
3-Ethyl-3-hydroxymethyloxetane 5029-67-4, 2-Iodopyridine
5798-75-4, 4-Bromobenzoic acid ethyl ester 7719-09-7, Thionyl
chloride 14996-61-3, Iridium trichloride hydrate 30030-25-2
30525-89-4, Paraformaldehyde 58327-60-9, 7-Propyl-8-quinolinol
59016-93-2, 4-(Hydroxymethyl)phenylboronic acid 76283-09-5,
4-Bromo-2-fluorobenzyl bromide
(method for manufacturing light-emitting element,
light-emitting device, and electronic apparatus)
IT 1710-98-1P 49743-87-5P 69135-05-3P 96411-61-9P 421553-47-1P
890844-70-9P 950590-42-8P 950590-43-9P 950590-44-0P
950590-45-1P 950590-46-2P 950590-47-3P 950590-49-5P
950590-50-8P 950590-51-9P 950590-52-0P 950590-53-1P
950590-57-5P 950590-59-7P 950598-61-5P 950598-62-6P

10/594,762

950598-64-8P 950598-69-3P 950598-70-6P 950598-71-7P
950598-73-9P

(method for manufacturing light-emitting element,
light-emitting device, and electronic apparatus)

IT 950590-48-4P 950590-54-2P 950590-55-3P 950590-56-4P
950590-58-6P 950590-61-1P 950590-62-2P 950598-63-7P
950598-65-9P 950598-66-0P 950598-67-1P 950598-68-2P
950598-72-8P

(method for manufacturing light-emitting element,
light-emitting device, and electronic apparatus)

IT 7429-90-5, Aluminum, uses 7440-70-2, Calcium, uses
(method for manufacturing light-emitting element,
light-emitting device, and electronic apparatus)

OS.CITING REF COUNT: 1 THERE ARE 1 CAPLUS RECORDS THAT CITE THIS
RECORD (1 CITINGS)

L62 ANSWER 4 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2006:1178076 HCAPLUS Full-text

DOCUMENT NUMBER: 146:89819

TITLE: Enhanced performance in organic light-
emitting diodes with copolymers containing
both tris(8-hydroxyquinoline) aluminum and
8-hydroxyquinoline lithium groups

AUTHOR(S): Du, N. Y.; Tian, R. Y.; Peng, J. B.; Mei, Q. B.;
Lu, M. G.

CORPORATE SOURCE: Key Laboratory of Polymer Materials for
Electronics, Guangdong Guangzhou Institute of
Chemistry, Chinese Academy of Sciences, Guangzhou,
510650, Peop. Rep. China

SOURCE: Journal of Applied Polymer Science (2006
, 102(5), 4404-4410

CODEN: JAPNAB; ISSN: 0021-8995

PUBLISHER: John Wiley & Sons, Inc.

DOCUMENT TYPE: Journal

LANGUAGE: English

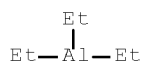
ED Entered STN: 09 Nov 2006

AB The authors synthesized novel copolymers containing both tris(8-
hydroxyquinoline) Al (Alq3) and 8-hydroxyquinoline Li (Liq) groups as emitting
layers for use in conventional two-layer organic light-emitting diodes. The
network structure and thermal stability of these materials is described. The
optical and electroluminescent properties of the copolymers were also studied.
The performance optimization of the devices with the copolymers through the
variation of the ratio of Alq3 to Liq is described. A mechanism responsible
for the improved electron injection is put forward.

IT 97-93-8, Triethylaluminum, reactions 148-24-3,
8-Hydroxyquinoline, reactions
(enhanced performance in organic light-emitting
diodes with copolymers containing both tris(8-hydroxyquinoline)
aluminum and 8-hydroxyquinoline lithium groups)

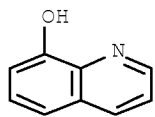
RN 97-93-8 HCAPLUS

CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

ST org LED copolymer tris hydroxyquinoline aluminum lithium

IT Electroluminescence
Electroluminescent devices
Glass substrates
luminescence
Optical absorption
UV and visible spectra
(enhanced performance in organic light-emitting diodes with copolymers containing both tris(8-hydroxyquinoline) aluminum and 8-hydroxyquinoline lithium groups)

IT 50926-11-9, Indium tin oxide 126213-51-2, PEDOT
(enhanced performance in organic light-emitting diodes with copolymers containing both tris(8-hydroxyquinoline) aluminum and 8-hydroxyquinoline lithium groups)

IT 97-93-8, Triethylaluminum, reactions 127-09-3, Sodium acetate 148-24-3, 8-Hydroxyquinoline, reactions 150-76-5, p-Methoxyphenol 868-77-9 1310-65-2, Lithium hydroxide
(enhanced performance in organic light-emitting diodes with copolymers containing both tris(8-hydroxyquinoline) aluminum and 8-hydroxyquinoline lithium groups)

IT 847506-46-1P 851593-62-9P
(enhanced performance in organic light-emitting diodes with copolymers containing both tris(8-hydroxyquinoline) aluminum and 8-hydroxyquinoline lithium groups)

IT 847506-46-1DP, derivs. 851593-62-9DP, derivs.
(enhanced performance in organic light-emitting diodes with copolymers containing both tris(8-hydroxyquinoline) aluminum and 8-hydroxyquinoline lithium groups)

IT 7429-90-5, Aluminum, uses
(enhanced performance inorganic light-emitting diodes with copolymers containing both tris(8-hydroxyquinoline) aluminum and 8-hydroxyquinoline lithium groups)

OS.CITING REF COUNT: 2 THERE ARE 2 CAPLUS RECORDS THAT CITE THIS RECORD (2 CITINGS)

REFERENCE COUNT: 22 THERE ARE 22 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L62 ANSWER 5 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2006:717587 HCAPLUS Full-text

DOCUMENT NUMBER: 145:176961

TITLE: Preparation of aluminum tris(8-hydroxyquinoline)/silicon oxide complex luminescent material with improved chemical stability and luminous intensity

INVENTOR(S): Zeng, Hongyu; Shi, Jianlin

PATENT ASSIGNEE(S): Shanghai Institute of Ceramics, Chinese Academy of Sciences, Peop. Rep. China
 SOURCE: Faming Zhuanli Shenqing Gongkai Shuomingshu, 9 pp.
 CODEN: CNXXEV
 DOCUMENT TYPE: Patent
 LANGUAGE: Chinese
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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CN 1803971	A	20060719	CN 2005-10112410	20051230

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PRIORITY APPLN. INFO.: CN 2005-10112410 20051230

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ED Entered STN: 25 Jul 2006

AB The title luminescent material for organic light emitting diode (OLED) device is prepared by: (1) grafting organic reactive group onto 8-hydroxyquinoline (HQ) for functional modification, (2) dissolving in ethanol, and adding silane coupling agent to obtain a silanized complex (SiHQ), (3) mixing with DMF, adding tetra-Et orthosilicate (TEOS), deionized water, and Al³⁺ solution, stirring, and drying to obtain the final product, wherein the molar ratio of SiHQ to TEOS is 1:(5-60). The process is simple and can be carried out in solution. The obtained material has an emission spectrum within blue light range and has advantages of high luminescent intensity, high chemical stability to water and oxygen, long service life, and low cost.

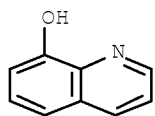
IT 148-24-3, 8-Hydroxyquinoline, processes 22537-23-1

, Aluminum 3+, processes

(preparation of aluminum tris(8-hydroxyquinoline)/silicon oxide complex luminescent material with improved chemical stability and luminous intensity)

RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



RN 22537-23-1 HCAPLUS

CN Aluminum, ion (Al³⁺) (CA INDEX NAME)

Al³⁺

CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

ST aluminum hydroxyquinoline silicon oxide complex luminescent material prepn

IT Coupling agents

luminescent substances

(preparation of aluminum tris(8-hydroxyquinoline)/silicon oxide complex

luminescent material with improved chemical stability and
luminous intensity)

IT Silanes

(preparation of aluminum tris(8-hydroxyquinoline)/silicon oxide complex
luminescent material with improved chemical stability and
luminous intensity)

IT 78-10-4, Tetraethyl orthosilicate 148-24-3,
8-Hydroxyquinoline, processes 22537-23-1, Aluminum 3+,
processes

(preparation of aluminum tris(8-hydroxyquinoline)/silicon oxide complex
luminescent material with improved chemical stability and
luminous intensity)

L62 ANSWER 6 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2006:674276 HCAPLUS Full-text

DOCUMENT NUMBER: 145:301732

TITLE: Design and synthesis of Alq3-functionalized SBA-15
mesoporous material

AUTHOR(S): Wang, Hongsu; Huang, Jiahui; Wu, Shujie; Xu, Chen;
Xing, Lihong; Xu, Ling; Kan, Qiubin

CORPORATE SOURCE: Department of Chemistry, Jilin University,
Changchun, 130023, Peop. Rep. China

SOURCE: Materials Letters (2006), 60(21-22),
2662-2665

CODEN: MLETDJ; ISSN: 0167-577X

PUBLISHER: Elsevier B.V.

DOCUMENT TYPE: Journal

LANGUAGE: English

ED Entered STN: 13 Jul 2006

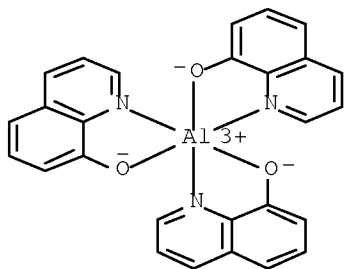
AB A luminescent organic mol. aluminum tris(8-hydroxyquinoline) (Alq3) has been
successfully introduced in the pores of amino-functionalized mesoporous SBA-15
(APS-SBA-15). An obvious blue-shifted photoluminescence (PL) of Alq3 was
observed In the pores of APS-SBA-15, the Alq3 organic mols. exhibited
efficient and intense PL as monomers and the emission intensities increased
with increasing Alq3 concentration

IT 2085-33-8DP, silane-base

(design and synthesis of Alq3-functionalized SBA-15 mesoporous
material)

RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)

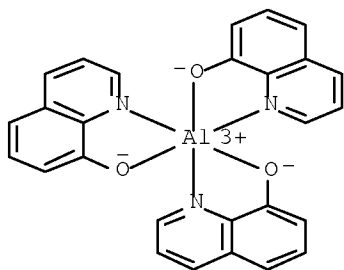


IT 2085-33-8

(design and synthesis of Alq3-functionalized SBA-15 mesoporous
material)

RN 2085-33-8 HCAPLUS

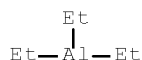
CN Aluminum, tris(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



IT 97-93-8, Triethyl aluminum, reactions 148-24-3,
8-Hydroxyquinoline, reactions
(design and synthesis of Alq3-functionalized SBA-15 mesoporous
material)

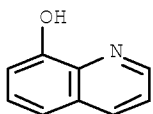
RN 97-93-8 HCAPLUS

CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other
Related Properties)

Section cross-reference(s): 78

ST Alq3 functionalized SBA mesoporous material luminescence
pore distribution synthesis

IT Luminescent substances
(design and synthesis of Alq3-functionalized SBA-15 mesoporous
material)

IT Luminescence

Pore size

Pore size distribution

Surface structure

X-ray diffraction

(of Alq3-functionalized SBA-15 mesoporous material)

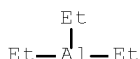
IT 2085-33-8DP, silane-base

(design and synthesis of Alq3-functionalized SBA-15 mesoporous
material)

IT 2085-33-8
 (design and synthesis of Alq3-functionalized SBA-15 mesoporous material)
 IT 97-93-8, Triethyl aluminum, reactions 148-24-3,
 8-Hydroxyquinoline, reactions 919-30-2, 3-Aminopropyltriethoxysilane
 2598-30-3, 5-Formyl-8-hydroxyquinoline
 (design and synthesis of Alq3-functionalized SBA-15 mesoporous material)
 OS.CITING REF COUNT: 7 THERE ARE 7 CAPLUS RECORDS THAT CITE THIS
 RECORD (7 CITINGS)
 REFERENCE COUNT: 21 THERE ARE 21 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

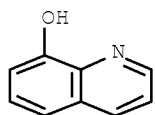
L62 ANSWER 7 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2006:452762 HCAPLUS Full-text
 DOCUMENT NUMBER: 145:104019
 TITLE: End-capped polystyrene with 8-hydroxyquinoline
 group by ATRP method
 AUTHOR(S): Liu, Cheng-Mei; Qiu, Jin-Jun; Bao, Rui; Xu, Yan;
 Cheng, Xiao-Ju; Hu, Fen
 CORPORATE SOURCE: Department of Chemistry, Huazhong University of
 Science and Technology, Wuhan, 430074, Peop. Rep.
 China
 SOURCE: Polymer (2006), 47(9), 2962-2969
 CODEN: POLMAG; ISSN: 0032-3861
 PUBLISHER: Elsevier Ltd.
 DOCUMENT TYPE: Journal
 LANGUAGE: English
 ED Entered STN: 16 May 2006

AB 8-Hydroxyquinoline end-capped polystyrene was prepared through atom transfer
 free radical polymerization (ATRP) with 8-(5-chloromethyl) quinolyl acetate as
 initiator. The results indicated that this polymerization is a first order
 reaction with respect to monomer conversion. The mol. weight increased
 linearly with monomer consumption and very narrow distribution of mol. weight
 was obtained (polydispersity index less than 1.2). The FT-IR and NMR results
 show that the 8-hydroxyquinoline group was chemical bonded to the polymer end
 and there is nearly one 8-hydroxyquinoline group in per polymer chain. All
 those data show that polymerization of styrene at such conditions displayed
 living characters. The polymer with 8-hydroxyquinoline end group reacted with
 triethylaluminum to form polymeric light-emitting complex and single layer
 LED was prepared by common spin-coating method. The peak wavelength of LED
 based on synthesized polymeric complex was around 570 nm.
 IT 97-93-8DP, Triethylaluminum, derivative with 8-hydroxyquinoline
 derivative capped polystyrene
 (ATRP kinetics of styrene catalyzed with 8-hydroxyquinoline derivative)
 RN 97-93-8 HCAPLUS
 CN Aluminum, triethyl- (CA INDEX NAME)



IT 148-24-3, 8-Hydroxyquinoline, reactions
 (in preparation of initiator containing 8-hydroxyquinoline group for ATRP
 of
 styrene)

RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



CC 35-4 (Chemistry of Synthetic High Polymers)
 Section cross-reference(s): 73
 ST light emitting coating hydroxyquinoline
 capped polystyrene ATRP
 IT Electroluminescent devices
 (LED prepared with end-capped polystyrene containing
 8-hydroxyquinoline group)
 IT 97-93-8DF, Triethylaluminum, derivative with 8-hydroxyquinoline
 derivative capped polystyrene
 (ATRP kinetics of styrene catalyzed with 8-hydroxyquinoline derivative)
 IT 50-00-0, Formaldehyde, reactions 75-36-5, Acetyl chloride
 148-24-3, 8-Hydroxyquinoline, reactions 7647-01-0, Hydrogen
 chloride, reactions
 (in preparation of initiator containing 8-hydroxyquinoline group for ATRP
 of

styrene)

OS.CITING REF COUNT: 5 THERE ARE 5 CAPLUS RECORDS THAT CITE THIS
 RECORD (5 CITINGS)
 REFERENCE COUNT: 28 THERE ARE 28 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 8 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2006:138274 HCAPLUS Full-text
 DOCUMENT NUMBER: 144:282934
 TITLE: Method for preparing aluminum 8-hydroxyquinoline
 complex as blue-light organic
 electroluminescent material
 INVENTOR(S): Xu, Bingshe; Wang, Hua; Hao, Yuying; Zhou, Hefeng;
 Li, Jie; Ruan, Limin
 PATENT ASSIGNEE(S): Taiyuan University of Technology, Peop. Rep. China
 SOURCE: Faming Zhuanli Shenqing Gongkai Shuomingshu, 19
 pp.
 CODEN: CNXXEV
 DOCUMENT TYPE: Patent
 LANGUAGE: Chinese
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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CN 1597669	A	20050323	CN 2004-10012430	20040719
			<--	
CN 1283628	C	20061108		
PRIORITY APPLN. INFO.:			CN 2004-10012430	20040719
			<--	

ED Entered STN: 15 Feb 2006

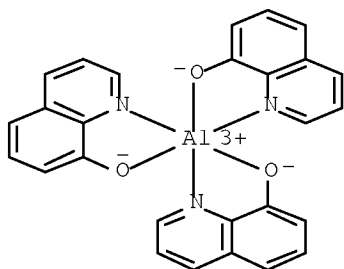
AB The title organic electroluminescent material is prepared from 8-hydroxyquinoline crystal, anhydrous aluminum acetate, anhydrous methanol, acetone, N,N'-dimethyl formamide and pyridine by carrying out reaction under nitrogen protection, washing, filtering, drying, vacuum heating, maintaining the temperature, cooling, purifying by recrystn., and analyzing to obtain the final product. This method has advantages of simple process, plentiful raw materials, high product quality, low manufacturing cost, etc.

IT 2085-33-8F, Alq3

(method for preparing aluminum 8-hydroxyquinoline complex as blue-light organic electroluminescent material)

RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)

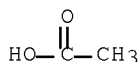


IT 139-12-8, Aluminum acetate 148-24-3,
8-Hydroxyquinoline, reactions

(method for preparing aluminum 8-hydroxyquinoline complex as blue-light organic electroluminescent material)

RN 139-12-8 HCAPLUS

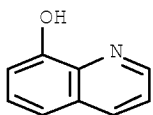
CN Acetic acid, aluminum salt (3:1) (CA INDEX NAME)



●1/3 Al

RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



IC ICM C07D215-24

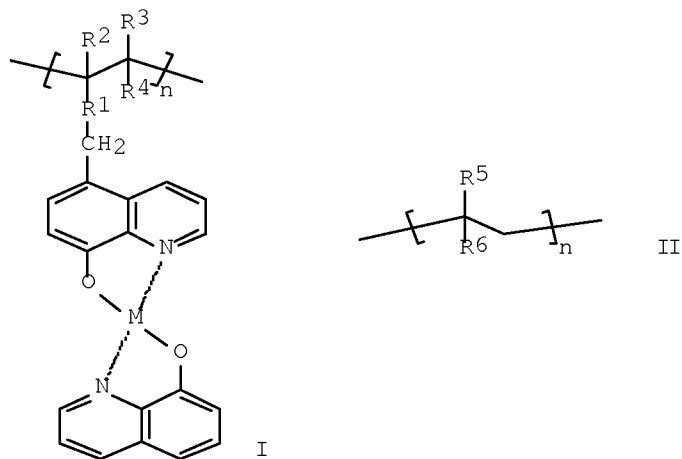
ICS C07F005-06

CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
 Section cross-reference(s): 27
 ST aluminum hydroxyquinoline complex blue org ~~electroluminescent~~
 material prepn
 IT ~~luminescent~~ substances
 (~~electroluminescent~~; method for preparing aluminum
 8-hydroxyquinoline complex as blue-light organic
~~electroluminescent~~ material)
 IT Recrystallization
 (method for preparing aluminum 8-hydroxyquinoline complex as
 blue-light organic ~~electroluminescent~~ material)
 IT 2085-33-8P, Alq3
 (method for preparing aluminum 8-hydroxyquinoline complex as
 blue-light organic ~~electroluminescent~~ material)
 IT 64-19-7, Acetic acid, formation (nonpreparative)
 (method for preparing aluminum 8-hydroxyquinoline complex as
 blue-light organic ~~electroluminescent~~ material)
 IT 67-56-1, Methanol, uses 67-64-1, Acetone, uses 68-12-2, uses
 110-86-1, Pyridine, uses 7727-37-9, Nitrogen, uses
 (method for preparing aluminum 8-hydroxyquinoline complex as
 blue-light organic ~~electroluminescent~~ material)
 IT 139-12-8, Aluminum acetate 148-24-3,
 8-Hydroxyquinoline, reactions
 (method for preparing aluminum 8-hydroxyquinoline complex as
 blue-light organic ~~electroluminescent~~ material)

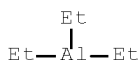
L62 ANSWER 9 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2006:136159 HCAPLUS Full-text
 DOCUMENT NUMBER: 144:192599
 TITLE: Preparation of monomers and copolymers containing
 8-hydroxyquinoline metal complexes
 INVENTOR(S): Du, Naiying; Lu, Mangeng; Mei, Qunbo
 PATENT ASSIGNEE(S): Guangzhou Institute of Chemistry, Chinese Academy
 of Sciences, Peop. Rep. China
 SOURCE: Faming Zhuanli Shenqing Gongkai Shuomingshu, 13
 pp.
 CODEN: CNXXEV
 DOCUMENT TYPE: Patent
 LANGUAGE: Chinese
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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CN 1594382	A	20050316	CN 2004-10027706	20040618
			<--	
CN 1240733	C	20060208		
PRIORITY APPLN. INFO.:			CN 2004-10027706	20040618
			<--	

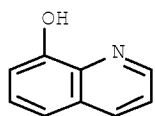
ED Entered STN: 14 Feb 2006
 GI



- AB A linear polymer with a mol. weight of 20000-100000, contains structural unit (I) and (II) at a molar ratio of 1:0.5-200, wherein M is a metal, R¹ is C₂-18 alkyl, ester, ether or amino, R², R³, R⁴, R⁵ and R⁶ are selected from H and C₁-18 alkyl. This copolymer is prepared by free-radical polymerization of 1 part 8-hydroxyquinoline metal complex containing vinyl monomer with one polymerizable functional group and 1-1000 parts vinyl monomer (e.g., allyl alc., vinylphenyl chloride, acryloyl chloride, styrene, C₃-18 unsatd. acid, C₃-18 unsatd. ester) in 5-500 parts polar organic solvent (e.g., anhydrous ethanol, THF, toluene, xylene, chloroform, benzene) in the presence of 0.01-0.5 parts free-radical initiator (e.g., BPO, AIBN) at 20-200° for 1-20 h, precipitating with methanol. The polymer may be used as luminescent material in organic electroluminescence flat panel display device and electron transport material. Thus, a luminescent polymer is prepared by copolymerizing 60 g 2-hydroxyethyl methacrylate with 10.0 g 8-hydroxyquinoline aluminum complex of Al³⁺, 2-[(8-hydroxy-5-quinolinyl)methoxy]ethyl methacrylate and 8-hydroxyquinoline.
- IT 97-93-8, Triethyl aluminum, reactions 148-24-3, 8-Hydroxyquinoline, reactions
(preparation of monomers and copolymers containing 8-hydroxyquinoline metal complexes)
- RN 97-93-8 HCAPLUS
- CN Aluminum, triethyl- (CA INDEX NAME)



- RN 148-24-3 HCAPLUS
- CN 8-Quinololinol (CA INDEX NAME)



IC ICM C08F226-06
ICS C09K011-06; C08F002-06; C08F004-34
CC 35-2 (Chemistry of Synthetic High Polymers)
Section cross-reference(s): 76
ST hydroxyquinoline aluminum complex prepn; ~~luminescent~~
hydroxyquinoline complex hydroxyethyl methacrylate copolymer
IT ~~Electroluminescent~~ devices
(displays; preparation of monomers and copolymers containing
8-hydroxyquinoline metal complexes)
IT ~~Luminescent~~ screens
(~~electroluminescent~~; preparation of monomers and copolymers
containing 8-hydroxyquinoline metal complexes)
IT 75-01-4, Vinyl chloride, reactions 97-93-8, Triethyl
aluminum, reactions 148-24-3, 8-Hydroxyquinoline,
reactions 555-31-7, Isopropanol Aluminumsalt 557-34-6, Zinc
acetate 868-77-9, 2-Hydroxyethyl methacrylate 920-46-7,
Methacrylic chloride 1310-65-2, Lithium hydroxide 1577-22-6,
5-Hexenoic acid 1592-20-7, 4-Vinylbenzylchloride 4053-44-5,
8-Hydroxy-5-Hydroxymethylquinoline 7446-70-0, Aluminum chloride,
reactions 7646-85-7, Zinc chloride, reactions 10136-57-9,
5-Chloromethyl-8-Hydroxyquinoline 34825-70-2, 6-Amino-1-hexene
81748-72-3, 5-Aminomethyl-8-Hydroxyquinoline
(preparation of monomers and copolymers containing 8-hydroxyquinoline metal
complexes)

L62 ANSWER 10 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2006:31888 HCAPLUS Full-text

DOCUMENT NUMBER: 144:124548

TITLE: Use of metal complexes for immobilizing target
molecules

INVENTOR(S): Muir, Benjamin Ward; Barden, Michael C.; Rylatt,
Dennis Brian; Maeji, N. Joe; Hillyard, Carmel
Judith; Gorse, Alain-Dominique Jean-Pierre

PATENT ASSIGNEE(S): Bio-Layer Pty. Ltd., Australia

SOURCE: PCT Int. Appl., 118 pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
-----	----	-----	-----	-----
WO 2006002472	A1	20060112	WO 2005-AU966	20050630

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W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA,
CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI,
GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM,
KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN,
MW, MX, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU,
SC, SD, SE, SG, SK, SL, SM, SY, TJ, TM, TN, TR, TT, TZ, UA,
UG, US, UZ, VC, VN, YU, ZA, ZM, ZW

10/594,762

RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU,
IE, IS, IT, LT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF,
BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG,
BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW,
AM, AZ, BY, KG, KZ, MD, RU, TJ, TM

AU 2005259833 A1 20060112 AU 2005-259833 20050630

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EP 1773866 A1 20070418 EP 2005-756657 20050630

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R: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU,
IE, IS, IT, LI, LT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR

JP 2008516189 T 20080515 JP 2007-519560 20050630

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US 20090209049 A1 20090820 US 2008-571422 20080114

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PRIORITY APPLN. INFO.: US 2004-585261P P 20040702

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US 2005-645053P P 20050118

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WO 2005-AU966 W 20050630

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ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

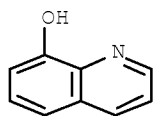
ED Entered STN: 13 Jan 2006

AB A method of immobilizing a target mol. on a substrate, which comprises
exposing the target mol. to the substrate in the presence of a metal complex,
wherein the target mol. is an unmodified target mol., and wherein the metal
complex is selected to provide a stable binding interaction between the target
mol. and the substrate.

IT 148-24-3D, 8-Hydroxyquinoline, complex ligand
7440-66-6D, Zinc, complexes 10043-01-3, Alum
(use of metal complexes for immobilizing target mols.)

RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



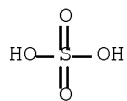
RN 7440-66-6 HCAPLUS

CN Zinc (CA INDEX NAME)

Zn

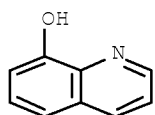
RN 10043-01-3 HCAPLUS

CN Sulfuric acid, aluminum salt (3:2) (CA INDEX NAME)

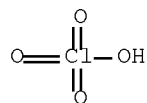


●2/3 Al

IT 148-24-3, 8-Hydroxyquinoline, reactions 10025-64-6
 (use of metal complexes for immobilizing target mols.)
 RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



RN 10025-64-6 HCAPLUS
 CN Perchloric acid, zinc salt, hydrate (2:1:6) (CA INDEX NAME)

●3 H₂O

●1/2 Zn

IC ICM C07K001-22
 ICS C07K017-06; G01N033-547
 CC 9-16 (Biochemical Methods)
 Section cross-reference(s): 1
 IT 521-31-3, Luminol
 (use of metal complexes for immobilizing target mols.)
 IT 64-19-7D, Acetic acid, salts 66-71-7D, 1,10-Phenanthroline, complex
 ligand 69-72-7D, Salicylic acid, complex ligand 107-15-3D,
 Ethylenediamine, complex ligand 110-18-9D, complex ligand
 142-73-4D, Iminodiacetic acid, complex ligand 144-62-7D, Oxalic
 acid, complex ligand 148-24-3D, 8-Hydroxyquinoline,
 complex ligand 7439-89-6D, Iron, complexes 7439-96-5D, Manganese,
 complexes 7439-98-7D, Molybdenum, complexes 7440-02-0D, Nickel,
 complexes 7440-06-4D, Platinum, complexes 7440-16-6D, Rhodium,
 complexes 7440-18-8D, Ruthenium, complexes 7440-20-2D, Scandium,
 complexes 7440-32-6D, Titanium, complexes 7440-47-3D, Chromium,
 complexes 7440-48-4D, Cobalt, complexes 7440-50-8D, Copper,

complexes 7440-62-2D, Vanadium, complexes 7440-66-6D,
Zinc, complexes 10043-01-3, Alum

(use of metal complexes for immobilizing target mols.)

IT 61-49-4, N- ω -Methyltryptamine 66-71-7, 1,10-Phenanthroline
91-21-4, 1,2,3,4-Tetrahydroisoquinoline 103-67-3, Benzylmethylamine
103-76-4, 1-(2-Hydroxyethyl)piperazine 109-01-3, 1-Methylpiperazine
109-83-1, 2-(Methylamino)ethanol 109-85-3, 2-Methoxyethylamine
110-68-9, N-Methylbutylamine 110-85-0, Piperazine, reactions
110-91-8, Morpholine, reactions 111-42-2, Diethanolamine, reactions
111-92-2, Dibutylamine 111-94-4, 3,3'-Iminodipropionitrile
111-95-5 123-75-1, Pyrrolidine, reactions 123-90-0, Thiomorpholine
124-40-3, Dimethylamine, reactions 139-13-9, Nitrilotriacetic acid
142-25-6, N,N,N'-Trimethylethylenediamine 142-84-7, Dipropylamine
~~148-24-3~~, 8-Hydroxyquinoline, reactions 504-78-9,
Thiazolidine 589-08-2, N-Methylphenethylamine 603-35-0,
Triphenylphosphine, reactions 622-26-4, 4-Piperidineethanol
627-37-2, N-Methylallylamine 693-05-0,
N-Methyl- β -alaninenitrile 1066-30-4, Chromium acetate
2439-54-5, N-Methyloctylamine 3490-06-0, N-Methylhomoveratrylamine
4753-75-7, N-Methylfurfurylamine 5638-76-6,
2-(2-Methylaminoethyl)pyridine 7088-89-3 7705-08-0, Iron(III)
chloride, reactions 7720-83-4, Titanium(IV) iodide 7789-68-6,
Titanium(IV) bromide ~~10025-64-6~~ 10031-25-1, Chromium
bromide 10031-26-2, Iron(III) bromide 10049-08-8, Ruthenium
chloride 10101-53-8, Chromium Sulfate 10141-00-1, Chrome alum
10294-46-9 13349-82-1 13446-57-6, Molybdenum(III) bromide
13478-33-6, Cobalt perchlorate hexahydrate 13520-61-1, Nickel
perchlorate hexahydrate 13537-21-8, Chromium(III) perchlorate
13548-38-4, Chromium nitrate 13889-98-0, 1-Acetylpiperazine
14014-88-1, Ruthenium tribromide 21359-99-9, Chromium perchlorate
32231-06-4, 1-Piperonylpiperazine 35161-71-8, N-Methylpropargylamine
35794-11-7, 3,5-Dimethylpiperidine 55147-94-9, Chromium perchlorate
hexahydrate 207569-11-7 220835-52-9, Platinum iodide 320589-77-3
698999-57-4 873196-27-1 873196-29-3

(use of metal complexes for immobilizing target mols.)

OS.CITING REF COUNT: 1 THERE ARE 1 CAPLUS RECORDS THAT CITE THIS
RECORD (1 CITINGS)
REFERENCE COUNT: 9 THERE ARE 9 CITED REFERENCES AVAILABLE FOR
THIS RECORD. ALL CITATIONS AVAILABLE IN THE
RE FORMAT

L62 ANSWER 11 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2005:1216411 HCAPLUS Full-text

DOCUMENT NUMBER: 143:471965

TITLE: Process to make metal complexes with volatile
liquid metal compounds

INVENTOR(S): Boone, James E.; Prindle, John C.

PATENT ASSIGNEE(S): Albemarle Corporation, USA

SOURCE: PCT Int. Appl., 21 pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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WO 2005108372	A1	20051117	WO 2004-US10505	20040405
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W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA,

10/594,762

CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI,
GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP,
KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW,
MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD,
SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ,
VC, VN, YU, ZA, ZM, ZW

RW: BW, GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AM,
AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE,
DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PL, PT,
RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW,
ML, MR, NE, SN, TD, TG

PRIORITY APPLN. INFO.:

WO 2004-US10505

20040405

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OTHER SOURCE(S): CASREACT 143:471965; MARPAT 143:471965

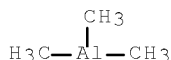
ED Entered STN: 17 Nov 2005

AB Processes for making metal complexes that are useful in organic light emitting devices (OLEDs) involve reacting a volatile liquid metal compound with a compound that has at least one hydroxyl (OH) group, such as 8-hydroxyquinoline. Exemplary volatile liquid metal compds. include trimethylaluminum, triethylaluminum, triisobutylaluminum, diisobutylaluminum hydride, dimethylaluminum chloride, and diethylaluminum chloride. One useful metal complex that can be produced is tris(8-hydroxyquinolinato)aluminum (Alq3) via reaction of Et3Al and 8-hydroxyquinoline in toluene at 0-40°.

IT 75-24-1, Trimethylaluminum 97-93-8,
Triethylaluminum, reactions 148-24-3, 8-Hydroxyquinoline,
reactions 148-24-3D, 8-Quinolinol, substituted derivs.
(preparation of tris(hydroxyquinolinato)aluminum and related metal
complexes of hydroxy-containing ligands via volatile liquid metal compound
precursors)

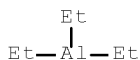
RN 75-24-1 HCAPLUS

CN Aluminum, trimethyl- (CA INDEX NAME)



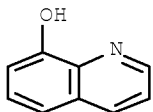
RN 97-93-8 HCAPLUS

CN Aluminum, triethyl- (CA INDEX NAME)

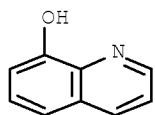


RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)

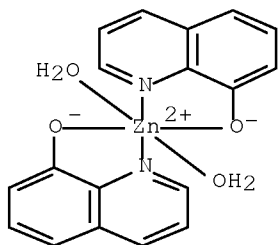


IC ICM C07D215-40
 ICS C09K011-06; C07F005-06
 CC 78-7 (Inorganic Chemicals and Reactions)
 Section cross-reference(s): 29, 73
 IT Electroluminescent devices
 Volatile substances
 (preparation of tris(hydroxyquinolinato)aluminum and related metal
 complexes of hydroxy-containing ligands via volatile liquid metal compound
 precursors)
 IT 75-24-1, Trimethylaluminum 96-10-6, Diethylaluminum
 chloride, reactions 97-93-8, Triethylaluminum, reactions
 100-99-2, Triisobutylaluminum, reactions 148-24-3,
 8-Hydroxyquinoline, reactions 148-24-3D, 8-Quinolinol,
 substituted derivs. 557-20-0, Diethylzinc 865-37-2,
 Dimethylaluminum hydride 871-27-2, Diethylaluminum hydride
 1184-58-3, Dimethylaluminum chloride 1191-15-7, Diisobutylaluminum
 hydride 12075-68-2, Ethylaluminum sesquichloride 12542-85-7,
 Methylaluminum sesquichloride 18123-20-1, 4-Hydroxyacridine
 71651-78-0, 3-(2-Benzothiazolyl)-4-hydroxy-2H-1-benzopyran-2-one
 (preparation of tris(hydroxyquinolinato)aluminum and related metal
 complexes of hydroxy-containing ligands via volatile liquid metal compound
 precursors)
 REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

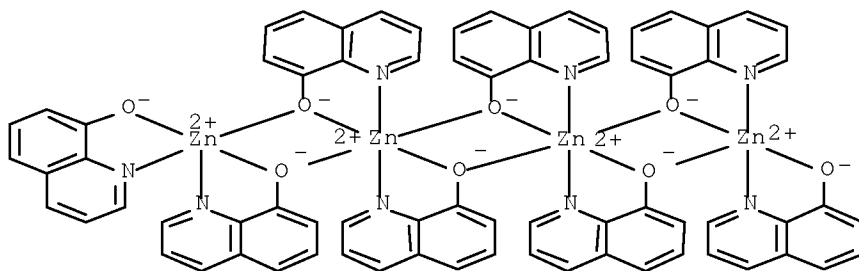
L62 ANSWER 12 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2005:1053853 HCAPLUS Full-text
 DOCUMENT NUMBER: 144:29041
 TITLE: The effects of crystal structure on optical
 absorption/photoluminescence of
 bis(8-hydroxyquinoline)zinc
 AUTHOR(S): Xu, Bing-she; Hao, Yu-ying; Wang, Hua; Zhou,
 He-feng; Liu, Xu-guang; Chen, Ming-wei
 CORPORATE SOURCE: College of Materials Science and Engineering,
 Taiyuan University of Technology, Shanxi, 030024,
 Peop. Rep. China
 SOURCE: Solid State Communications (2005),
 136(6), 318-322
 CODEN: SSCO4; ISSN: 0038-1098
 PUBLISHER: Elsevier Ltd.
 DOCUMENT TYPE: Journal
 LANGUAGE: English
 ED Entered STN: 03 Oct 2005
 AB The transformation processes of 2 types of bis(8-hydroxyquinolinato)zinc:
 Znq2(H2O)2 and anhydrous (Znq2)4 were studied by XRD, UV spectra, SEM, DSC,

and TG. The effects of crystal structure on optical properties of bis(8-hydroxyquinoline)zinc were analyzed. $\text{Znq}_2(\text{H}_2\text{O})_2$ can be transformed into anhydrous $(\text{Znq}_2)_4$ during heating under vacuum. Reversal transformation occurs by the interaction between CHCl_3 and $(\text{Znq}_2)_4$. But $(\text{Znq}_2)_4$ was partially transformed into Znq_2 dihydrate by the interaction between EtOH and $(\text{Znq}_2)_4$. The different mol. structure results in different crystal stacking and electronic structure, thereby affect its optical properties.

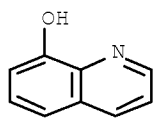
IT 15279-82-0P, DiaquaBis(8-hydroxyquinolinato)zinc
(preparation and crystal structure effects on optical absorption/
luminescence and thermal decomposition of)
RN 15279-82-0 HCAPLUS
CN Zinc, diaquabis(8-quinolinolato- $\kappa\text{N}1, \kappa\text{O}8$)- (CA INDEX NAME)



IT 97477-20-8P
(preparation and crystal structure effects on optical absorption/
luminescence of)
RN 97477-20-8 HCAPLUS
CN Zinc, hexakis[μ -(8-quinolinolato- $\kappa\text{N}1, \kappa\text{O}8: \kappa\text{O}8$)]bis(8-quinolinolato- $\kappa\text{N}1, \kappa\text{O}8$)tetra-, stereoisomer (9CI) (CA INDEX NAME)



IT 148-24-3, 8-Hydroxyquinoline, processes
(reaction with zinc sulfate in presence of triethylamine)
RN 148-24-3 HCAPLUS
CN 8-Quinolinol (CA INDEX NAME)



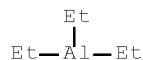
CC 73-4 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
 Section cross-reference(s): 75, 78
 ST zinc hydroxyquinoline hydrate anhyd tetramer crystal structure
 luminescence UV
 IT Crystal structure-property relationship
 (luminescence; of zinc hydroxyquinolinato complex monomer dihydrate and anhydrous tetramer)
 IT 15279-82-0P, DiaquaBis(8-hydroxyquinolinato)zinc
 (preparation and crystal structure effects on optical absorption/luminescence and thermal decomposition of)
 IT 97477-20-8P
 (preparation and crystal structure effects on optical absorption/luminescence of)
 IT 148-24-3, 8-Hydroxyquinoline, processes
 (reaction with zinc sulfate in presence of triethylamine)
 OS.CITING REF COUNT: 6 THERE ARE 6 CAPLUS RECORDS THAT CITE THIS RECORD (6 CITINGS)
 REFERENCE COUNT: 15 THERE ARE 15 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L62 ANSWER 13 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2005:654922 HCAPLUS Full-text
 DOCUMENT NUMBER: 143:306883
 TITLE: Poly(styrene)-Supported Alq3 and BPh2q
 AUTHOR(S): Wang, Xian-Yong; Weck, Marcus
 CORPORATE SOURCE: School of Chemistry and Biochemistry, Georgia Institute of Technology, Atlanta, GA, 30332-0400, USA
 SOURCE: Macromolecules (2005), 38(17), 7219-7224
 CODEN: MAMOBX; ISSN: 0024-9297
 PUBLISHER: American Chemical Society
 DOCUMENT TYPE: Journal
 LANGUAGE: English

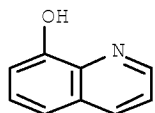
ED Entered STN: 28 Jul 2005

AB We describe the synthesis of 8-hydroxyquinoline-tethered poly(styrene)s as modular precursors for functionalization with metalloquinolates to form either tris(8-hydroxyquinoline)aluminum (Alq3) or 8-hydroxyquinoline biphenylboron (BPh2q) pendant polymers. All polymers, both in solution and in the solid state, show similar luminescent properties as their corresponding reference compds. Alq3 and BPh2q while retaining excellent solution-processing properties. These results clearly indicate that the poly(styrene) backbone does not interfere with the photophys. properties of the pendant Alq3 and BPh2q chromophores but endows solution processability to the materials.
 IT 97-93-8DP, Triethylaluminum, reaction products
 (chloromethyl)styrene-styrene copolymer derivs. and hydroxyquinoline
 148-24-3DP, 8-Hydroxyquinoline, reaction products
 (chloromethyl)styrene-styrene copolymer derivs. and triethylaluminum
 (preparation and properties of poly(styrene)-supported tris(hydroxyquinoline)aluminum and hydroxyquinoline biphenylboron pendant polymers)

RN 97-93-8 HCAPLUS
 CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



CC 37-3 (Plastics Manufacture and Processing)
 Section cross-reference(s): 35, 73

IT Chromophores
 Luminescence
 (preparation and properties of poly(styrene)-supported
 tris(hydroxyquinoline)aluminum and hydroxyquinoline biphenylboron
 pendant polymers)

IT 97-93-3DP, Triethylaluminum, reaction products
 (chloromethyl)styrene-styrene copolymer derivs. and hydroxyquinoline
 148-24-3DP, 8-Hydroxyquinoline, reaction products
 (chloromethyl)styrene-styrene copolymer derivs. and triethylaluminum
 960-71-4DP, Triphenylboron, reaction products
 (chloromethyl)styrene-styrene copolymer derivs. 1074-82-4DP,
 Potassium phthalimide, reaction products with
 (chloromethyl)styrene-styrene copolymer and formylhydroxyquinoline,
 hydrogenated, reaction products with triphenylboron or
 hydroxyquinoline and triethylaluminum 2598-30-3DP,
 5-Formyl-8-hydroxyquinoline, reaction products with
 (chloromethyl)styrene-styrene copolymer and potassium phthalimide,
 hydrogenated, reaction products with triphenylboron or
 hydroxyquinoline and triethylaluminum 29464-22-0DP,
 p-(Chloromethyl)styrene-styrene copolymer, reaction products with
 potassium phthalimide and formylhydroxyquinoline, hydrogenated,
 reaction products with triphenylboron or hydroxyquinoline and
 triethylaluminum
 (preparation and properties of poly(styrene)-supported
 tris(hydroxyquinoline)aluminum and hydroxyquinoline biphenylboron
 pendant polymers)

OS.CITING REF COUNT: 33 THERE ARE 33 CAPLUS RECORDS THAT CITE THIS
 RECORD (33 CITINGS)

REFERENCE COUNT: 28 THERE ARE 28 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 14 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2005:426178 HCAPLUS Full-text
 DOCUMENT NUMBER: 142:454113

TITLE: Organic ~~electroluminescent~~ devices
 having a stability-enhancing layer
 INVENTOR(S): Liao, Liang-Sheng; Klubek, Kevin P.
 PATENT ASSIGNEE(S): Eastman Kodak Company, USA
 SOURCE: U.S. Pat. Appl. Publ., 13 pp.
 CODEN: USXXCO
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
US 20050104511	A1	20050519	US 2003-713523	20031114
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US 7138763	B2	20061121		
WO 2005050753	A2	20050602	WO 2004-US35918	20041029
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WO 2005050753	A3	20050728		
W:	AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW			
RW:	BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG			

PRIORITY APPLN. INFO.: US 2003-713523 A 20031114
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ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

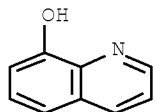
ED Entered STN: 19 May 2005

AB An organic ~~light-emitting~~ device with enhanced operational stability comprising an anode; a hole-~~transporting~~ layer disposed over the anode; a ~~light-emitting~~ layer disposed over the hole-~~transporting~~ layer for producing light in response to hole-electron recombination, wherein the ~~light-emitting~~ layer includes at least one organic host material and one ~~organic luminescent~~ dopant material; a stability-enhancing layer disposed in contact with the ~~light-emitting~~ layer, wherein the stability-enhancing layer includes at least one organic host material and one inorg. dopant material; an electron-~~transporting~~ layer disposed over the stability-enhancing layer; and a cathode disposed over the electron-~~transporting~~ layer.

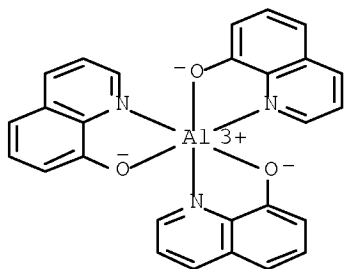
IT 148-24-3D, 8-Hydroxyquinoline, complexes 2085-33-8
 , Alq3 7429-90-5, Aluminum, properties 7440-55-3
 , Gallium, properties 7440-66-6, Zinc, properties
 (organic ~~electroluminescent~~ devices having
 stability-enhancing layer)

RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



RN 2085-33-8 HCAPLUS
 CN Aluminum, tris(8-quinolinolato- κ N1, κ O8)- (CA INDEX NAME)



RN 7429-90-5 HCAPLUS
 CN Aluminum (CA INDEX NAME)

Al

RN 7440-55-3 HCAPLUS
 CN Gallium (CA INDEX NAME)

Ga

RN 7440-66-6 HCAPLUS
 CN Zinc (CA INDEX NAME)

Zn

IC ICM H05B033-00
 ICS H05B033-14; H05B033-22
 INCL 313504000; 313503000; 313506000
 CC 73-12 (Optical, Electron, and Mass Spectroscopy and Other
 Related Properties)
 Section cross-reference(s): 76
 ST org electroluminescent device stability enhancing layer
 IT Electroluminescent devices
 (displays; organic electroluminescent devices having
 stability-enhancing layer)
 IT Luminescent screens
 (electroluminescent; organic
 electroluminescent devices having stability-enhancing

layer)

IT Electroluminescent devices
(organic electroluminescent devices having
stability-enhancing layer)

IT Alkali metals, properties
Alkaline earth metals
Fluoropolymers, properties
Metals, properties
Rare earth metals, properties
Transition metals, properties
(organic electroluminescent devices having
stability-enhancing layer)

IT 148-24-3D, 8-Hydroxyquinoline, complexes 1662-01-7, Bphen
2085-33-8, Alq3 7429-90-5, Aluminum, properties
7429-91-6, Dysprosium, properties 7439-91-0, Lanthanum, properties
7439-93-2, Lithium, properties 7439-94-3, Lutetium, properties
7439-95-4, Magnesium, properties 7439-96-5, Manganese, properties
7439-98-7, Molybdenum, properties 7440-00-8, Neodymium, properties
7440-02-0, Nickel, properties 7440-05-3, Palladium, properties
7440-06-4, Platinum, properties 7440-09-7, Potassium, properties
7440-10-0, Praseodymium, properties 7440-17-7, Rubidium, properties
7440-19-9, Samarium, properties 7440-22-4, Silver, properties
7440-23-5, Sodium, properties 7440-24-6, Strontium, properties
7440-27-9, Terbium, properties 7440-30-4, Thulium, properties
7440-31-5, Tin, properties 7440-39-3, Barium, properties
7440-45-1, Cerium, properties 7440-46-2, Cesium, properties
7440-50-8, Copper, properties 7440-52-0, Erbium, properties
7440-53-1, Europium, properties 7440-54-2, Gadolinium, properties
7440-55-3, Gallium, properties 7440-57-5, Gold, properties
7440-64-4, Ytterbium, properties 7440-65-5, Yttrium, properties
7440-66-6, Zinc, properties 7440-70-2, Calcium, properties
7440-74-6, Indium, properties 50926-11-9, Indium tin oxide
80663-92-9 123847-85-8, Npb 274905-73-6
(organic electroluminescent devices having
stability-enhancing layer)

OS.CITING REF COUNT: 3 THERE ARE 3 CAPLUS RECORDS THAT CITE THIS
RECORD (3 CITINGS)

REFERENCE COUNT: 28 THERE ARE 28 CITED REFERENCES AVAILABLE FOR
THIS RECORD. ALL CITATIONS AVAILABLE IN THE
RE FORMAT

L62 ANSWER 15 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2005:345979 HCAPLUS Full-text

DOCUMENT NUMBER: 142:381971

TITLE: Organic electroluminescent devices
employing an organometallic complex-containing
layer adjacent to a reducing metal and fabrication
process of electroluminescent devices

INVENTOR(S): Kido, Junji; Matsumoto, Toshio; Nakada, Takeshi;
Kawamura, Norifumi

PATENT ASSIGNEE(S): International Manufacturing and Engineering
Services Co., Ltd., Japan

SOURCE: Eur. Pat. Appl., 33 pp.
CODEN: EPXXDW

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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EP 1524707	A2	20050420	EP 2004-24611	20041015
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EP 1524707	A3	20060426		
R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC,				
PT, IE, SI, LT, LV, FI, RO, MK, CY, AL, TR, BG, CZ, EE, HU,				
PL, SK, HR				
JP 2005123094	A	20050512	JP 2003-358401	20031017
			<--	
CN 1610473	A	20050427	CN 2004-10080504	20040930
			<--	
US 20050084713	A1	20050421	US 2004-966708	20041015
			<--	
KR 2005037400	A	20050421	KR 2004-83343	20041018
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KR 858106	B1	20080910		
PRIORITY APPLN. INFO.:			JP 2003-358401	A 20031017
			<--	

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

ED Entered STN: 22 Apr 2005

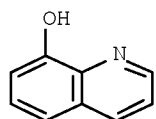
AB Organic ~~electroluminescent~~ devices are described which comprise a substrate, an anode layer; an organic structure including at least one light-emissive layer; a low resistance electron-transporting layer including a mixed layer of an electron-donating metal dopant and an organic compound; an organometallic complex-containing layer including an organometallic complex compound containing at least one metal ion selected from an alkaline metal ion, an alkaline earth metal ion and a rare earth metal ion; a reducing reaction generating layer; and a cathode layer, in that order. At least one of the anode layer and the cathode layer is transparent. The reducing reaction generating layer is a layer produced by depositing on the organometallic complex-containing layer a thermally reducible metal capable of reducing the metal ion in the organometallic complex compound in a vacuum to the corresponding metal, followed by causing an oxidation-reduction reaction between them.

IT 25387-93-3

(organic ~~electroluminescent~~ devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of ~~electroluminescent~~ devices)

RN 25387-93-3 HCAPLUS

CN 8-Quinolinol, lithium salt (1:1) (CA INDEX NAME)



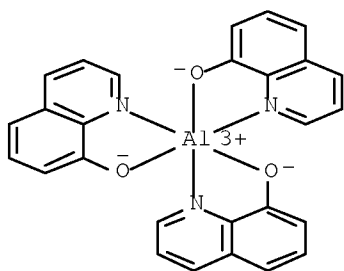
● Li

IT 2085-33-8, Aluminum tris(8-hydroxyquinolinato)

(organic ~~electroluminescent~~ devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of ~~electroluminescent~~ devices)

RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



- IT 7429-90-5, Aluminum, uses
(thermally reducible metal; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- RN 7429-90-5 HCAPLUS
- CN Aluminum (CA INDEX NAME)
- Al
- IC ICM H01L051-20
- CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
Section cross-reference(s): 76
- ST OLED organometallic complex reducing metal fabrication; org electroluminescent device organometallic complex reducing metal manuf
- IT Organometallic compounds
(alkaline earth compds.; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Organometallic compounds
(alkali metal compds.; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Sputtering
(cathode deposition by; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Vapor deposition process
(electron-beam, thermally reducible metal deposition by; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Vapor deposition process
(laser ablation, thermally reducible metal deposition by; organic electroluminescent devices employing organometallic

- complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Electroluminescent devices
Semiconductor device fabrication
(organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Coordination compounds
Organometallic compounds
(organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Alkali metals, uses
Alkaline earth metals
Rare earth metals, uses
(organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal resulting in formation of)
- IT Alkali metal compounds
Alkaline earth compounds
Rare earth compounds
(organometallic compds.; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Organometallic compounds
(rare earth compds.; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Vapor deposition process
(resistive heating; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT Reduction
(thermal; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT 50926-11-9, Indium tin oxide
(electrode; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT 123847-85-8, α -NPD
(hole-transporting layer; organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT 25387-93-3
(organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT 2085-33-8, Aluminum tris(8-hydroxyquinolino) 4733-39-5, Bathocuproine 7440-46-2, Cesium, uses
(organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication process of electroluminescent devices)
- IT 7439-93-2P, Lithium, uses
(organic electroluminescent devices employing organometallic complex-containing layer adjacent to reducing metal and fabrication

process of electroluminescent devices)

IT 7429-90-5, Aluminum, uses
(thermally reducible metal; organic electroluminescent
devices employing organometallic complex-containing layer adjacent to
reducing metal and fabrication process of
electroluminescent devices)

IT 7440-21-3, Silicon, uses 7440-32-6, Titanium, uses 7440-33-7,
Tungsten, uses 7440-67-7, Zirconium, uses
(thermally reducible metal; organic electroluminescent
devices employing organometallic complex-containing layer adjacent to
reducing metal and fabrication process of
electroluminescent devices)

OS.CITING REF COUNT: 2 THERE ARE 2 CAPLUS RECORDS THAT CITE THIS
RECORD (8 CITINGS)

REFERENCE COUNT: 3 THERE ARE 3 CITED REFERENCES AVAILABLE FOR
THIS RECORD. ALL CITATIONS AVAILABLE IN THE
RE FORMAT

L62 ANSWER 16 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2005:119243 HCAPLUS Full-text

DOCUMENT NUMBER: 142:373950

TITLE: Synthesis, Characterization, and Photophysical
Properties of Iridium Complexes with an
8-Phenylquinoline Framework. The First
Six-Membered Chelated Iridium Complexes for
Electroluminescence

AUTHOR(S): Li, Hao-Chun; Chou, Pi-Tai; Hu, Ya-Hui; Cheng,
Yi-Ming; Liu, Rai-Shung

CORPORATE SOURCE: Department of Chemistry, National Tsing-Hua
University, Hsinchu, Taiwan

SOURCE: Organometallics (2005), 24(6), 1329-1335
CODEN: ORGND7; ISSN: 0276-7333

PUBLISHER: American Chemical Society

DOCUMENT TYPE: Journal

LANGUAGE: English

OTHER SOURCE(S): CASREACT 142:373950

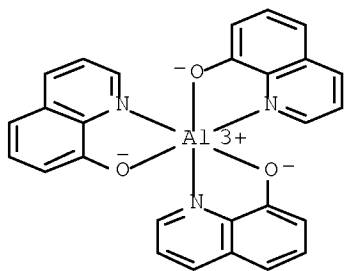
ED Entered STN: 11 Feb 2005

AB Six-membered chelated Ir complexes bearing an 8-phenylquinoline framework were prepared and characterized with an x-ray diffraction study. The photophys. properties of these complexes were examined with appropriate spectroscopic methods. The results, in combination with ab initio approaches, led the authors to clearly assign various electronic transition states. One salient feature for these red complexes is the appearance of a dual strong absorption band around 425-500 nm, which incorporates a state mixing between 1MLCT and π - π^* manifolds. These complexes show deep red phosphorescent emissions (650-680 nm), with short lifetimes of 1.7-3.0 μ s and moderate quantum yields of 0.05-0.11 in deaerated MeCN. The electroluminescence performance of these species shows a promising perspective in the OLED display. One representative, Ir[8-(3,5-difluorophenyl)quinoline]2(acac) (4c), shows an η ext value of 2.04% at J = 20 mA/cm² and the maximum brightness is 3427 cd/m² (x = 0.68, y = 0.32) with a full width at half-maximum of only 60 nm at 16 V, demonstrating the 1st six-membered chelated Ir complexes to suit applications in OLED devices.

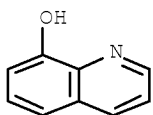
IT 2085-33-8, Tris(8-hydroxyquinoline)aluminum
(preparation and photophys. properties of cyclometalated iridium
complexes with phenylquinoline framework and six-membered chelated
ring with acetylacetonate)

RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato- κ N1, κ O8)- (CA INDEX NAME)



IT 148-24-3, 8-Hydroxyquinoline, reactions
 (preparation and photophys. properties of cyclometalated iridium
 complexes with phenylquinoline framework and six-membered chelated
 ring with acetylacetonate)
 RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



CC 29-13 (Organometallic and Organometalloidal Compounds)
 Section cross-reference(s): 22, 73, 74, 75
 ST iridium phenylquinoline cyclometalated prepn photophys
 electroluminescence; crystal structure iridium cyclometalated
 phenylquinoline fluoro prepn; mol structure iridium cyclometalated
 phenylquinoline fluoro
 IT Electroluminescent devices
 (organic LEDs; preparation and photophys. properties of
 cyclometalated iridium complexes with phenylquinoline framework and
 six-membered chelated ring with acetylacetonate)
 IT 2085-33-8, Tris(8-hydroxyquinoline)aluminum 4733-39-5,
 Bathocuproine 50926-11-9, ITO 58328-31-7 123847-85-8
 (preparation and photophys. properties of cyclometalated iridium
 complexes with phenylquinoline framework and six-membered chelated
 ring with acetylacetonate)
 IT 123-54-6, Acetylacetone, reactions 148-24-3,
 8-Hydroxyquinoline, reactions
 (preparation and photophys. properties of cyclometalated iridium
 complexes with phenylquinoline framework and six-membered chelated
 ring with acetylacetonate)
 OS.CITING REF COUNT: 35 THERE ARE 35 CAPLUS RECORDS THAT CITE THIS
 RECORD (35 CITINGS)
 REFERENCE COUNT: 52 THERE ARE 52 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 17 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2005:54153 HCAPLUS Full-text
 DOCUMENT NUMBER: 142:280485

TITLE: Synthesis and photophysical characterization of the free-radical copolymerization of metaloquinolate-pendant monomers with methyl methacrylate

AUTHOR(S): Du, Naiying; Tian, Renyu; Peng, Junbiao; Lu, Mangeng

CORPORATE SOURCE: Key Laboratory of Polymer Materials for Electronics, Guangdong Guangzhou Institute of Chemistry, Chinese Academy of Sciences, Guangzhou, 510650, Peop. Rep. China

SOURCE: Journal of Polymer Science, Part A: Polymer Chemistry (2004), Volume Date 2005, 43(2), 397-406
CODEN: JPACEC; ISSN: 0887-624X

PUBLISHER: John Wiley & Sons, Inc.

DOCUMENT TYPE: Journal

LANGUAGE: English

ED Entered STN: 20 Jan 2005

AB A series of novel metaloquinolate [aluminum quinolate (Alq3), zinc quinolate (Znq2), and lithium quinolate (Liq)]-containing copolymers were prepared. This is the first report of the synthesis of metaloquinolate-containing polymers by free-radical copolymerization. The structures of the metaloquinolate monomers and copolymers were characterized by ¹H NMR and Fourier-transform IR techniques. The differential scanning calorimetry and thermogravimetric analysis results showed that the copolymers were more thermally stable than the Me methacrylate homopolymer. The copolymers (<25 weight % Alq3, <20 weight % Znq2, or <15 weight % Liq) could be dissolved in common solvents without crosslinking. The UV-visible absorption and photoluminescence (PL) emission properties of the copolymers were consistent with the literature data of metaloquinolate complexes. The PL efficiencies of the metaloquinolate-containing copolymers with 25 weight % Alq3, 20 weight % Znq2, or 15 weight % Liq were 19.89, 13.24, and 11.82%, resp. The experimental results indicated that these kinds of materials could be used for practical applications in organic light-emitting diodes.

IT 97-93-8, Triethylaluminum, reactions 148-24-3, 8-Quinolinol, reactions
(in synthesis of hydroxyquinoline metal chelates for free-radical polymerization with Me methacrylate)

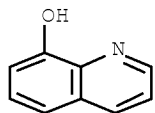
RN 97-93-8 HCAPLUS

CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



CC 35-4 (Chemistry of Synthetic High Polymers)
 ST metaloquinolate contg monomer radical polymn methyl methacrylate; zinc
 quinolate contg polymethacrylate prepn property; aluminum quinolate
 contg polymethacrylate prepn property; lithium quinolate contg
 polymethacrylate prepn property; light emitting
 diode metaloquinolate contg polymethacrylate
 IT ~~Electroluminescent~~ devices
 (synthesis and photophys. characterization of copolymers of
 metaloquinolate-pendant monomers and Me methacrylate for use in)
 IT Glass transition temperature
 Luminescence
 Molecular weight
 Polydispersity
 Solubility
 Thermal stability
 UV and visible spectra
 (synthesis and photophys. characterization of free-radical
 copolymn. of metaloquinolate-pendant monomers with Me methacrylate)
 IT 50-00-0, Formaldehyde, reactions 97-93-8,
 Triethylaluminum, reactions 123-31-9, Hydroquinol, reactions
~~148-24-3~~, 8-Quinolinol, reactions 557-20-0, Diethylzinc
 868-77-9, 2-Hydroxyethyl methacrylate 1310-65-2, Lithium hydroxide
 (in synthesis of hydroxyquinoline metal chelates for free-radical
 polymerization with Me methacrylate)
 OS.CITING REF COUNT: 16 THERE ARE 16 CAPLUS RECORDS THAT CITE THIS
 RECORD (16 CITINGS)
 REFERENCE COUNT: 28 THERE ARE 28 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 18 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2004:1080334 HCAPLUS Full-text
 DOCUMENT NUMBER: 142:47531
 TITLE: Method of reducing photoelectric device leakage
 current in conjugated polymer, and conjugated
 polymer composition
 INVENTOR(S): Chen, Kuo-Yu; Tuan, Chi-Shen; Teng, Wan-Jung;
 Chang, Shinn-Jen
 PATENT ASSIGNEE(S): Industrial Technology Research Institute, Taiwan
 SOURCE: U.S. Pat. Appl. Publ., 17 pp.
 CODEN: USXXCO
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

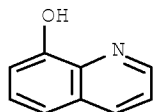
PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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US 20040250849	A1	20041216	US 2003-633708	20030805
			<--	
US 7026275	B2	20060411		
TW 255832	B	20060601	TW 2003-92115804	20030611
			<--	
PRIORITY APPLN. INFO.:			TW 2003-92115804	A 20030611
			<--	

ED Entered STN: 17 Dec 2004

AB A method of reducing the photoelec. device leakage current caused by residual
 metal ions in conjugated polymer. A chelating agent is added to a conjugated
 polymer material, thereby the conductivity and mobility of metal ions under an
 elec. field are reduced due to the chelation of metal ions by the chelating

agent; therefore, the leakage current is reduced and the stability of devices is improved. Also, the activity of metal ions is reduced after the metal ions are chelated by the chelating agent, improving the stability of the material and the devices. A conjugated polymer composition is also provided.

IT 148-24-3, 8-Hydroxyquinoline, processes
 (chelating agent; fabricating method of reducing photoelec. device leakage current in conjugated polymer by addition of chelating agents and conjugated polymer composition)
 RN 148-24-3 HCAPLUS
 CN 8-Quinololinol (CA INDEX NAME)



IT 7429-90-5, Aluminum, uses
 (contact; fabricating method of reducing photoelec. device leakage current in conjugated polymer by addition of chelating agents and conjugated polymer composition)
 RN 7429-90-5 HCAPLUS
 CN Aluminum (CA INDEX NAME)

A1

IC ICM H01L021-00
 INCL 136263000; 438149000; 438151000; 438057000; 438059000; 438463000
 CC 76-5 (Electric Phenomena)
 Section cross-reference(s): 38, 48, 52, 74
 IT Capacitors
 Chelating agents
 Electroluminescent devices
 Gettering
 Inductors
 Lasers
 Memory devices
 Photoelectric devices
 Resistors
 Solar cells
 Solvents
 Transistors
 (fabricating method of reducing photoelec. device leakage current in conjugated polymer by addition of chelating agents and conjugated polymer composition)
 IT 94-93-9, N,N'-Bis(salicylidene)ethylenediamine 148-24-3,
 8-Hydroxyquinoline, processes
 (chelating agent; fabricating method of reducing photoelec. device leakage current in conjugated polymer by addition of chelating agents and conjugated polymer composition)
 IT 7429-90-5, Aluminum, uses 7440-70-2, Calcium, uses
 (contact; fabricating method of reducing photoelec. device leakage

current in conjugated polymer by addition of chelating agents and
conjugated polymer composition)

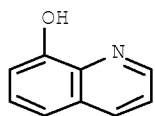
OS.CITING REF COUNT: 1 THERE ARE 1 CAPLUS RECORDS THAT CITE THIS
RECORD (1 CITINGS)
REFERENCE COUNT: 1 THERE ARE 1 CITED REFERENCES AVAILABLE FOR
THIS RECORD. ALL CITATIONS AVAILABLE IN THE
RE FORMAT

L62 ANSWER 19 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
ACCESSION NUMBER: 2004:1059398 HCAPLUS Full-text
DOCUMENT NUMBER: 142:24413
TITLE: ~~luminescent~~ organic-polymer/metal
complex for wet processable films and
process for producing thereof
INVENTOR(S): Kudo, Kazuaki; Kobayashi, Yasushi; Takayama,
Toshio; Sano, Hiroshi
PATENT ASSIGNEE(S): Nippon Light Metal Company, Ltd., Japan
SOURCE: PCT Int. Appl., 47 pp.
CODEN: PIXXD2
DOCUMENT TYPE: Patent
LANGUAGE: Japanese
FAMILY ACC. NUM. COUNT: 1
PATENT INFORMATION:

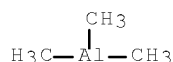
PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
WO 2004106389	A1	20041209	WO 2004-JP7904	20040601
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W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW				
RW: BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG				
JP 2005015752	A	20050120	JP 2003-311117	20030903
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JP 4295047	B2	20090715		
EP 1637545	A1	20060322	EP 2004-735677	20040601
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EP 1637545	B1	20091111		
R: DE, GB				
CN 1798776	A	20060705	CN 2004-80014974	20040601
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CN 100503655	C	20090624		
US 20060128940	A1	20060615	US 2005-559129	20051201
<--				
PRIORITY APPLN. INFO.:			JP 2003-156790	A 20030602
<--				
			JP 2003-311117	A 20030903
<--				
			WO 2004-JP7904	W 20040601
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ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT
ED Entered STN: 10 Dec 2004

- AB The present invention relates to a luminescent org .-polymer/metal complex polyQ·M·Kn-1 obtained by reacting a polymer ligand (polyQ) comprising a polymer and a side chain 8-hydroxyquinoline derivative through a spacer group, a 8-hydroxyquinoline derivative ligand (K), and a di- to tetravalent metal ion (Mn+), wherein the 8-hydroxyquinoline derivative ligand has a bulky substituent. Also provided is a luminescent org .-polymer/metal complex composition comprising the luminescent organic-polymer/metal complex and a low-mol. ligand. Thus, 26.2 g 8-hydroxyquinoline and hydro chloride were reacted in the presence of formaldehyde, 2-hydroxyethyl methacrylate was added therein and reacted to give 2-ethoxy methacrylate-substituted 8-hydroxyquinoline, 7.00 g of which was polymerized in the presence of 321 mg AIBN to give a polymer ligand, 800 mg of which was mixed with 6.64 g 7-(4-ethyl-1-methyloctyl)-8-hydroxyquinoline and reacted with 8.4 mmol trimethylaluminum to give a aluminum complex mixture showing luminescence at 400 nm (excitation at 533 nm) for both in solution and in film.
- IT 148-24-3, 8-Hydroxyquinoline, reactions
(reactant in polymer ligand preparation; preparation of luminescent organic-polymer/metal complexes for wet processable films)
- RN 148-24-3 HCAPLUS
- CN 8-Quinolinol (CA INDEX NAME)



- IT 75-24-1, Trimethylaluminum
(reactant in polymer ligand-metal complex preparation; preparation of luminescent organic-polymer/metal complexes for wet processable films)
- RN 75-24-1 HCAPLUS
- CN Aluminum, trimethyl- (CA INDEX NAME)



- IC ICM C08F008-42
ICS C08F020-36; C09K011-06; H05B033-14
- CC 38-3 (Plastics Fabrication and Uses)
Section cross-reference(s): 73
- ST luminescent org polymer metal complex wet
processable film process; hydroxyquinoline hydro chloride
formaldehyde reactant; aluminum polymeric ligand complex prep
- IT Coordination compounds
(polymer ligand-; preparation of luminescent org .-polymer/metal complexes for wet processable films)
- IT Ligands
(polymeric; preparation of luminescent org .-polymer/metal complexes for wet processable films)
- IT Luminescent substances

- (preparation of luminescent organic-polymer/metal complexes for wet processable films)
- IT 4053-45-6P 745782-29-0P 745782-35-8P 745782-37-0P
(intermediate in polymer ligand preparation; preparation of luminescent organic-polymer/metal complexes for wet processable films)
- IT 84953-68-4
(ligand; preparation of luminescent org
.-polymer/metal complexes for wet processable films)
- IT 95831-48-4P 745782-31-4P
(monomer in polymer ligand preparation; preparation of luminescent organic-polymer/metal complexes for wet processable films)
- IT 745782-32-5P 802985-76-8P
(polymer ligand; preparation of luminescent org
.-polymer/metal complexes for wet processable films)
- IT 7429-90-5DP, Aluminum, polymer complexes 73545-11-6DP, aluminum complexes 745782-32-5DP, aluminum complexes 802985-76-8DP, aluminum complexes
(preparation of luminescent organic-polymer/metal complexes for wet processable films)
- IT 18162-48-6, tert-Butyldimethylsilyl chloride
(protecting group in polymer ligand preparation; preparation of luminescent organic-polymer/metal complexes for wet processable films)
- IT 50-00-0, Formaldehyde, reactions 148-24-3, 8-Hydroxyquinoline, reactions 868-77-9, 2-Hydroxyethyl methacrylate 7647-01-0, Hydrochloric acid, reactions 73545-11-6
(reactant in polymer ligand preparation; preparation of luminescent organic-polymer/metal complexes for wet processable films)
- IT 75-24-1, Trimethylaluminum 555-31-7, Triisopropoxyaluminum
(reactant in polymer ligand-metal complex preparation; preparation of luminescent organic-polymer/metal complexes for wet processable films)

REFERENCE COUNT: 5 THERE ARE 5 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L62 ANSWER 20 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2004:1037594 HCAPLUS Full-text

DOCUMENT NUMBER: 142:206760

TITLE: Self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices

AUTHOR(S): Kwok, Chi-Chung; Yu, Sze-Chit; Sham, Iona H. T.; Che, Chi-Ming

CORPORATE SOURCE: Department of Chemistry and the HKU-CAS Joint Laboratory on New Materials, The University of Hong Kong, Hong Kong, Peop. Rep. China

SOURCE: Chemical Communications (Cambridge, United Kingdom) (2004), (23), 2758-2759
CODEN: CHCOFS; ISSN: 1359-7345

PUBLISHER: Royal Society of Chemistry

DOCUMENT TYPE: Journal

LANGUAGE: English

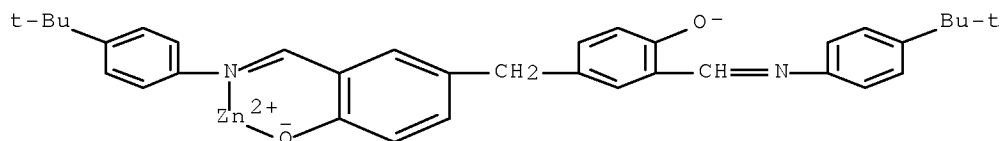
OTHER SOURCE(S): CASREACT 142:206760

ED Entered STN: 03 Dec 2004

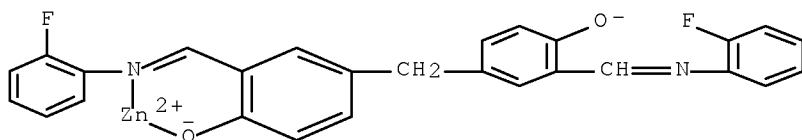
AB Thermally stable zinc(II) Schiff base polymers (decomposition temperature up to 461°; Mn = 13580 to 20440) formed by self-assembly reactions of zinc(II)

salts and salicylaldehyde monomers exhibit blue to yellow PL with quantum yields up to 0.34 in DMF; PLEDs employing these polymers as emitters give green or orange EL with turn-on voltage at 5 and 6 V and maximum efficiency of 2.0 and 2.6 cd A⁻¹ resp.

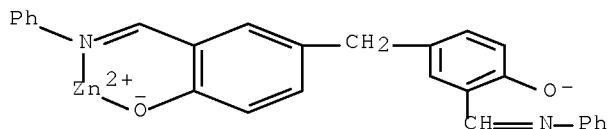
IT 837411-92-4P 837411-96-8P
 (polymeric; self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)
 RN 837411-92-4 HCAPLUS
 CN Zinc, [2-[[[4-(1,1-dimethylethyl)phenyl]imino-κN]methyl]-4-[[3-[[[4-(1,1-dimethylethyl)phenyl]imino]methyl]-4-hydroxyphenyl]methyl]phenolato(2-)-κO]- (CA INDEX NAME)



RN 837411-96-8 HCAPLUS
 CN Zinc, [2-[[[2-fluorophenyl]imino-κN]methyl]-4-[[3-[[[2-fluorophenyl]imino]methyl]-4-hydroxyphenyl]methyl]phenolato(2-)-κO]- (CA INDEX NAME)

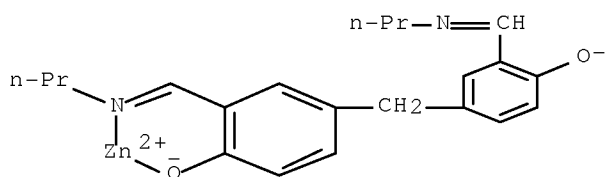


IT 75785-68-1P 837411-91-3P
 (polymeric; self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)
 RN 75785-68-1 HCAPLUS
 CN Zinc, [4-[[[4-hydroxy-3-[(phenylimino)methyl]phenyl]methyl]-2-[(phenylimino-κN)methyl]phenolato(2-)-κO]- (CA INDEX NAME)



RN 837411-91-3 HCAPLUS
 CN Zinc, [4-[[[4-hydroxy-3-[(propylimino)methyl]phenyl]methyl]-2-[(propylimino-κN)methyl]phenolato(2-)-κO]- (CA INDEX NAME)

NAME)

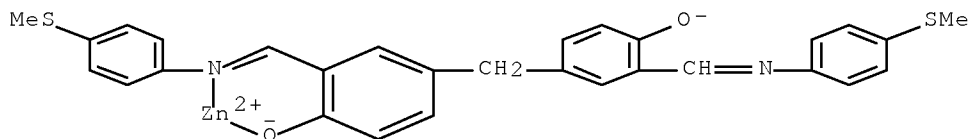


IT 837411-93-5P 837411-94-6P 837411-95-7P
837411-97-9P

(polymeric; self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)

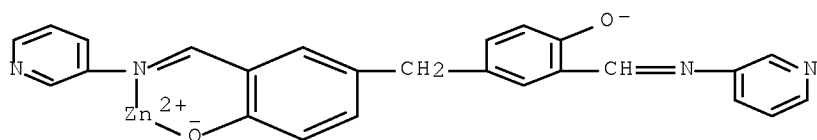
RN 837411-93-5 HCAPLUS

CN Zinc, [4-[[4-hydroxy-3-[[[4-(methylthio)phenyl]imino]methyl]phenyl]methyl]-2-[[[4-(methylthio)phenyl]imino-κN]methyl]phenolato(2-)-κO]- (CA INDEX NAME)



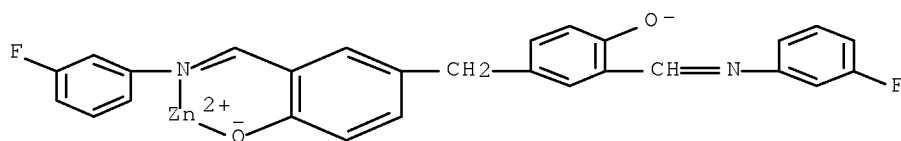
RN 837411-94-6 HCAPLUS

CN Zinc, [4-[[4-hydroxy-3-[(3-pyridinylimino)methyl]phenyl]methyl]-2-[(3-pyridinylimino-κN)methyl]phenolato(2-)-κO]- (CA INDEX NAME)

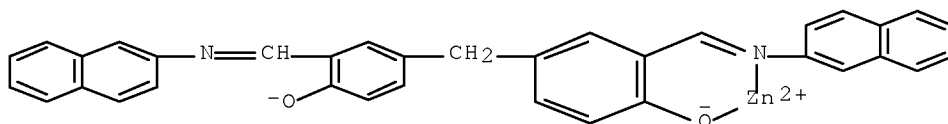


RN 837411-95-7 HCAPLUS

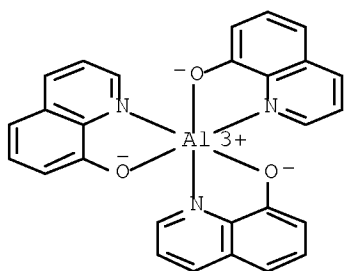
CN Zinc, [2-[[[3-fluorophenyl]imino-κN]methyl]-4-[[3-[[[3-fluorophenyl]imino]methyl]-4-hydroxyphenyl]methyl]phenolato(2-)-κO]- (CA INDEX NAME)



RN 837411-97-9 HCAPLUS
 CN Zinc, [4-[[4-hydroxy-3-[(2-naphthalenylimino)methyl]phenyl]methyl]-2-
 [(2-naphthalenylimino-κN)methyl]phenolato(2-)-κO]- (CA
 INDEX NAME)



IT 2085-33-8, Alq3
 (self-assembled zinc(II) Schiff base polymers for applications in
 polymer light-emitting devices containing)
 RN 2085-33-8 HCAPLUS
 CN Aluminum, tris(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related
 Properties)
 Section cross-reference(s): 36, 38, 76
 ST self assembled zinc Schiff base polymer electroluminescent
 device photoluminescence
 IT Polymers
 (Schiff base-containing, zinc; self-assembled zinc(II) Schiff base
 polymers for applications in polymer light-
 emitting devices)
 IT Luminescence, electroluminescence
 Surface structure
 Thermal stability
 (of self-assembled zinc(II) Schiff base polymers for applications
 in polymer light-emitting devices)

IT Electroluminescent devices
 (polymer; self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)

IT Electric current-potential relationship
 Self-assembly
 (self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)

IT Luminescence
 (visible; of self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)

IT 9003-53-6D, sulfonated
 (dopant for PEDOT; self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices containing)

IT 126213-51-2
 (doped with PSS; self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices containing)

IT 837411-92-4P 837411-96-8P
 (polymeric; self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)

IT 75785-68-1P 837411-91-3P
 (polymeric; self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)

IT 837411-93-5P 837411-94-6P 837411-95-7P
 837411-97-9P
 (polymeric; self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)

IT 62-53-3, Benzenamine, properties 91-59-8, 2-Naphthalenamine
 348-54-9 372-19-0 769-92-6 1783-81-9 3046-82-0
 (self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)

IT 462-08-8P, 3-Pyridinamine 17867-16-2P 20880-14-2P 835897-13-7P
 835897-14-8P 835897-15-9P 835897-16-0P 835897-17-1P
 835897-18-2P
 (self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices)

IT 2085-33-8, Alq3 4733-39-5, BCP
 (self-assembled zinc(II) Schiff base polymers for applications in polymer light-emitting devices containing)

OS.CITING REF COUNT: 13 THERE ARE 13 CAPLUS RECORDS THAT CITE THIS RECORD (13 CITINGS)

REFERENCE COUNT: 16 THERE ARE 16 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L62 ANSWER 21 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2004:1032472 HCAPLUS Full-text

DOCUMENT NUMBER: 142:187779

TITLE: Programmable polymer thin film and non-volatile memory device

AUTHOR(S): Ouyang, Jianyong; Chu, Chih-Wei; Szmanda, Charles R.; Ma, Liping; Yang, Yang

CORPORATE SOURCE: Department of Materials Science and Engineering, University of California, Los Angeles, CA, 90095, USA

SOURCE: Nature Materials (2004), 3(12), 918-922
 CODEN: NMAACR; ISSN: 1476-1122

PUBLISHER: Nature Publishing Group

DOCUMENT TYPE: Journal

LANGUAGE: English

ED Entered STN: 02 Dec 2004

AB Building on the success of organic electronic devices, such as light-emitting diodes and field-effect transistors, procedures for fabricating nonvolatile organic memory devices are now being explored. We demonstrate an organic memory device fabricated by solution processing. Programmable elec. bistability was observed in a device made from a polystyrene film containing gold nanoparticles and 8-hydroxyquinoline sandwiched between two metal electrodes. The as-prepared device, which is in a low-conductivity state, displays an abrupt transition to a high-conductivity state under an external bias of 2.8 V. These two states differ in conductivity by about four orders of magnitude. Applying a neg. bias of 1.8 V causes the device to return to the low-conductivity state. The electronic transition is attributed to the elec.-field-induced charge transfer between the gold nanoparticles and 8-hydroxyquinoline. The transition from the low- to the high-conductivity state takes place in nanoseconds, and is nonvolatile, indicating that the device may be used for low-cost, high-d. memory storage.

IT 7429-90-5, Aluminum, uses
(electrodes; programmable polymer thin film and nonvolatile memory device)

RN 7429-90-5 HCAPLUS

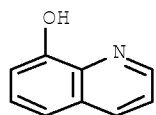
CN Aluminum (CA INDEX NAME)

A1

IT 148-24-3, 8-Hydroxyquinoline, uses
(programmable polymer thin film and nonvolatile memory device)

RN 148-24-3 HCAPLUS

CN 8-Quinololinol (CA INDEX NAME)



CC 76-14 (Electric Phenomena)
Section cross-reference(s): 38

IT 7429-90-5, Aluminum, uses
(electrodes; programmable polymer thin film and nonvolatile memory device)

IT 148-24-3, 8-Hydroxyquinoline, uses 9003-53-6, Polystyrene
(programmable polymer thin film and nonvolatile memory device)

OS.CITING REF COUNT: 247 THERE ARE 247 CAPLUS RECORDS THAT CITE THIS RECORD (247 CITINGS)

REFERENCE COUNT: 25 THERE ARE 25 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L62 ANSWER 22 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2004:823958 HCAPLUS Full-text

DOCUMENT NUMBER: 141:340538

TITLE: Organic/inorganic hybrid material, composition for synthesizing the same, and process for producing the hybrid material

INVENTOR(S): Seo, Satoshi; Nakashima, Harue; Nomura, Ryoji

PATENT ASSIGNEE(S): Semiconductor Energy Laboratory Co. Ltd., Japan

SOURCE: PCT Int. Appl., 99 pp.
CODEN: PIXXD2

DOCUMENT TYPE: Patent

LANGUAGE: Japanese

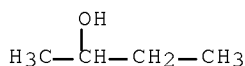
FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
WO 2004085543	A1	20041007	WO 2004-JP3610	20040317
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W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW				
RW: BW, GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG				
EP 1607446	A1	20051221	EP 2004-721373	20040317
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CN 1795241	A	20060628	CN 2004-80014783	20040317
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CN 100422269	C	20081001		
CN 101368006	A	20090218	CN 2008-10210659	20040317
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US 20040265253	A1	20041230	US 2004-809130	20040325
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US 7517470	B2	20090414		
US 20090206746	A1	20090820	US 2009-420548	20090408
<--				
PRIORITY APPLN. INFO.:			JP 2003-85688	A 20030326
<--				
			CN 2004-80014783	A3 20040317
<--				
			WO 2004-JP3610	W 20040317
<--				
			US 2004-809130	A3 20040325
<--				
ED	Entered STN: 08 Oct 2004			
AB	An organic/inorg. hybrid material contains an organic compound (functional chelating agent) which is capable of manifesting coloring, luminescence and semiconductor property functions through formation of a chelate with metal atom and is in pendant-form chelate coordination with the metal atom of metal oxide matrix. This organic/inorg. hybrid material can be synthesized by preparing a sol (coating composition) comprising a metal alkoxide and/or metal salt and a functional chelating agent and thereafter carrying out synthetic operation according to sol gel process. Thus, there can be synthesized an			

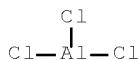
organic/inorg. hybrid material which has an organic group directly linked to a metal oxide matrix and consequently can manifest functions different from those of simple metal oxide. That is, a functional organic/inorg. hybrid material capable of manifesting coloring, luminescence or semiconductor properties can be realized by the organic group directly linked to a metal oxide matrix.

IT 2269-22-9 7446-70-0, Aluminum chloride,
processes
(organic/inorg. hybrid material having coloring, luminescence
or semiconductor properties)
RN 2269-22-9 HCAPLUS
CN 2-Butanol, aluminum salt (3:1) (CA INDEX NAME)

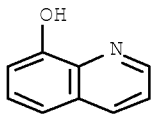


● 1/3 Al

RN 7446-70-0 HCAPLUS
CN Aluminum chloride (AlCl₃) (CA INDEX NAME)



IT 148-24-3DF, 8-Quinolinol, chelates with metal oxide matrix
1344-28-1F, Alumina, preparation
(organic/inorg. hybrid material having coloring, luminescence
or semiconductor properties)
RN 148-24-3 HCAPLUS
CN 8-Quinolinol (CA INDEX NAME)



RN 1344-28-1 HCAPLUS
CN Aluminum oxide (Al₂O₃) (CA INDEX NAME)

*** STRUCTURE DIAGRAM IS NOT AVAILABLE ***

IC ICM C09B057-10
ICS C09K011-06; C09D185-00; C09D001-00; C09D007-12; H05B033-14;
C03C017-32
CC 74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other
Reprographic Processes)
Section cross-reference(s): 42

ST org inorg hybrid coloring luminescence semiconductor
property

IT Metal alkoxides
(coating; organic/inorg. hybrid material having coloring,
luminescence or semiconductor properties)

IT Electroluminescent devices
(displays; organic/inorg. hybrid material having coloring,
luminescence or semiconductor properties)

IT Luminescent screens
(electroluminescent; organic/inorg. hybrid
material having coloring, luminescence or semiconductor
properties)

IT Coating materials
Coloring materials
Luminescent substances
Semiconductor materials
(organic/inorg. hybrid material having coloring,
luminescence or semiconductor properties)

IT Oxides (inorganic), uses
(organic/inorg. hybrid material having coloring, luminescence
or semiconductor properties)

IT 78-10-4D, Tetraethoxysilane, hydrolyzed 2269-22-9
7446-70-0, Aluminum chloride, processes
(organic/inorg. hybrid material having coloring, luminescence
or semiconductor properties)

IT 148-24-3DP, 8-Quinolinol, chelates with metal oxide matrix
1344-28-1P, Alumina, preparation 7631-86-9P, Silica,
preparation
(organic/inorg. hybrid material having coloring, luminescence
or semiconductor properties)

IT 141-97-9, Ethyl acetoacetate
(organic/inorg. hybrid material having coloring, luminescence
or semiconductor properties)

OS.CITING REF COUNT: 1 THERE ARE 1 CAPLUS RECORDS THAT CITE THIS
RECORD (1 CITINGS)

REFERENCE COUNT: 11 THERE ARE 11 CITED REFERENCES AVAILABLE FOR
THIS RECORD. ALL CITATIONS AVAILABLE IN THE
RE FORMAT

L62 ANSWER 23 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2004:702156 HCAPLUS Full-text

DOCUMENT NUMBER: 141:226346

TITLE: Metal 8-hydroxyquinoline-functionalized polymers
and their preparation for optical materials

INVENTOR(S): Weck, Marcus; Meyers, Amy

PATENT ASSIGNEE(S): Georgia Tech Research Corporation, USA

SOURCE: PCT Int. Appl., 88 pp.
CODEN: PIXXD2

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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WO 2004073030	A2	20040826	WO 2004-US3587	20040206
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WO 2004073030	A3	20040923		
W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA,				
CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI,				

10/594,762

GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP,
KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW,
MX, MZ, NA, NI
RW: BW, GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AT,
BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE,
IT, LU, MC, NL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI,
CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG
US 20050131175 A1 20050616 US 2004-773980 20040206
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US 7105617 B2 20060912
PRIORITY APPLN. INFO.: US 2003-445701P P 20030206
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US 2003-500000P P 20030904
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OTHER SOURCE(S): MARPAT 141:226346

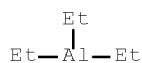
ED Entered STN: 27 Aug 2004

AB This invention relates to the synthesis of Mqn-containing monomeric compds., comprising a polymerizable moiety, an Mqn-moiety, and an optional chemical spacer therebetween, wherein q, in each instance, comprises an 8-hydroxyquinoline residue, M is a metal such as Mg, Zn, Al, Ga, or In, and n is 2 or 3 as the valence of the metal requires. For example, the polymerization of Znq2- or Alq3-containing monomers, in the presence or absence of a co-monomer, provided a Znq2- or Alq3-containing polymer, which retained the optical properties of Znq2 or Alq3 in solution, resp. The Mqn-containing polymers may be used in, among other things, the fabrication of light-emitting diodes (LEDs).

IT 97-93-8, Triethylaluminum, reactions 148-24-3,
8-Hydroxyquinoline, reactions
(metal 8-hydroxyquinoline-functionalized polymers and their preparation for optical materials)

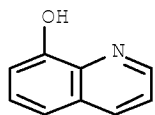
RN 97-93-8 HCAPLUS

CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



IC ICM H01L

CC 37-3 (Plastics Manufacture and Processing)
Section cross-reference(s): 73

IT Electroluminescent devices
(metal 8-hydroxyquinoline-functionalized polymers and their preparation for optical materials)

IT 97-93-8, Triethylaluminum, reactions 148-24-3,

8-Hydroxyquinoline, reactions 2598-30-3, 5-Formyl-8-hydroxyquinoline
 17016-12-5 511243-83-7, Bicyclo[2.2.1]hept-5-ene-2-hexanenitrile
 (metal 8-hydroxyquinoline-functionalized polymers and their preparation
 for optical materials)

OS.CITING REF COUNT: 3 THERE ARE 3 CAPLUS RECORDS THAT CITE THIS
 RECORD (3 CITINGS)
 REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 24 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2004:638852 HCAPLUS Full-text

DOCUMENT NUMBER: 141:342388

TITLE: Investigations on the electronic effects of the
 peripheral 4'-group on
 5-(4'-substituted)phenylazo-8-hydroxyquinoline
 ligands: zinc and aluminium complexes

AUTHOR(S): La Deda, Massimo; Grisolia, Annarita; Aiello,
 Iolinda; Crispini, Alessandra; Ghedini, Mauro;
 Belviso, Sandra; Amati, Mario; Lelj, Francesco

CORPORATE SOURCE: LASCAMM, Unita INSTM della Calabria, Dipartimento
 di Chimica, Universita degli Studi della Calabria,
 Arcavacata di Rende), I-87036, Italy

SOURCE: Dalton Transactions (2004), (16),
 2424-2431

CODEN: DTARAF; ISSN: 1477-9226

PUBLISHER: Royal Society of Chemistry

DOCUMENT TYPE: Journal

LANGUAGE: English

OTHER SOURCE(S): CASREACT 141:342388

ED Entered STN: 09 Aug 2004

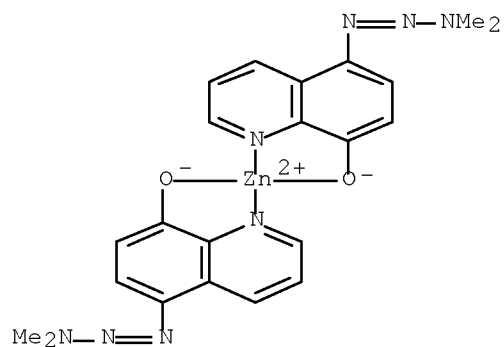
AB 5-(4'-Substituted)phenylazo-8-hydroxyquinolines (H[L-R]; R = NMe₂, I, C₂H₅,
 II, Bu, III, CMe₃, IV, H, V and F, VI) were prepared and the corresponding
 Zn[L-R]₂ (1a-6a) and Al[L-R]₃ (1b-6b) complexes successfully synthesized.
 These compds. were studied to design new mol. materials with enhanced electron
 transport properties. The obtained species were extensively characterized by
 absorption and emission spectra and by cyclic voltammetric measurements.
 Exptl. and computational results show that the Zn[L-NMe₂].2H₂O (1a) and Al[L-
 NMe₂] (1b) complexes only feature luminescence (at 620 and 600 nm), resp. The
 unique effects, which are induced by the N:N-C₆H₄-NMe₂ group, are further
 proved by a reversible electron transfer process detected by cyclic
 voltammetry. These outcomes, discussed from theor. calcns. performed on the
 {H[L-NMe₂]}-, H[L-NMe₂] and {H[L-NMe₂]}+ species, suggest that metal complexes
 formed by 5-(4'-N,N-dimethylamino)phenylazo-8-hydroxyquinoline should be
 considered as electron transport materials suitable for applications in
 photonic devices.

IT ~~769936-04-1~~

(cyclic voltammetry and luminescence spectra of)

RN 769936-04-1 HCAPLUS

CN Zinc, bis[5-(3,3-dimethyl-1-triazenyl)-8-quinolinolato-
 κN1,κO8]-, (T-4)- (9CI) (CA INDEX NAME)

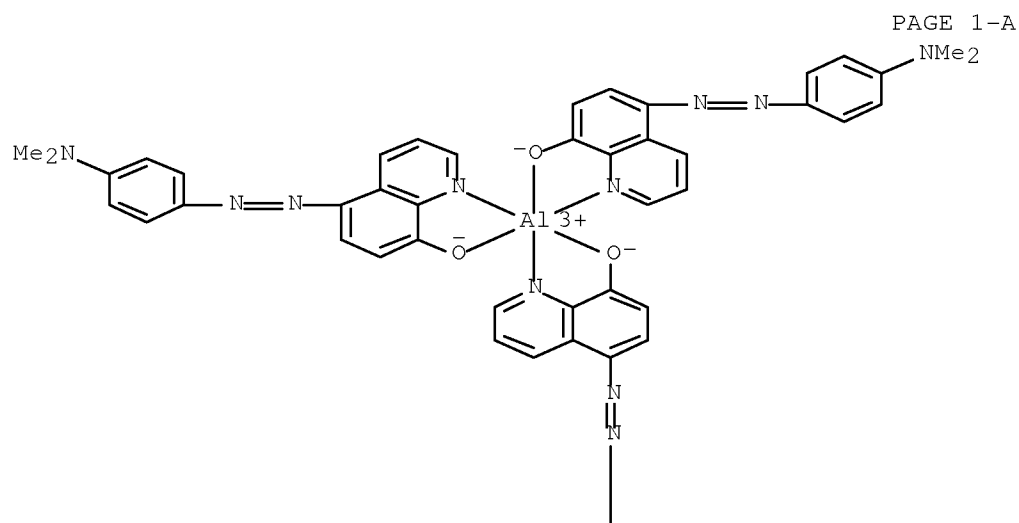


IT 769935-97-9P

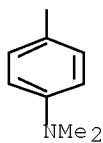
(preparation and cyclic voltammetry and fluorescence of)

RN 769935-97-9 HCAPLUS

CN Aluminum, tris[5-[[4-(dimethylamino)phenyl]azo]-8-quinolinolato- κ N1, κ O8]- (9CI) (CA INDEX NAME)



PAGE 2-A



IT 14708-01-1P 769935-93-5P 769935-94-6P
769935-95-7P 769935-96-8P 769935-98-0P

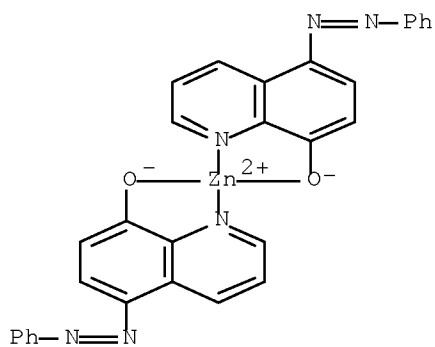
10/594,762

769935-99-1P 769936-00-7P 769936-01-8P
769936-02-9P

(preparation and cyclic voltammetry of)

RN 14708-01-1 HCAPLUS

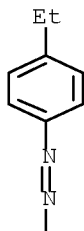
CN Zinc, bis[5-(phenylazo)-8-quinolinolato-κN1,κO8]-, (T-4)-
(9CI) (CA INDEX NAME)

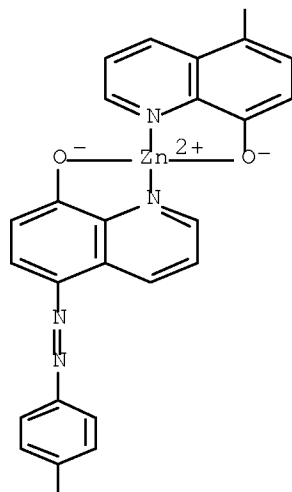


RN 769935-93-5 HCAPLUS

CN Zinc, bis[5-[(4-ethylphenyl)azo]-8-quinolinolato-κN1,κO8]-
, (T-4)- (9CI) (CA INDEX NAME)

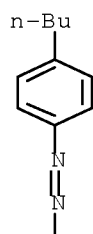
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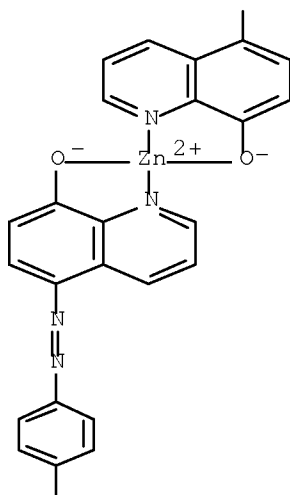


RN 769935-94-6 HCAPLUS

CN Zinc, bis[5-[(4-butylphenyl)azo]-8-quinolinolato-κN1,κO8]-
, (T-4)- (9CI) (CA INDEX NAME)



PAGE 2-A

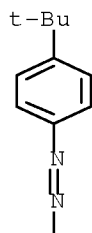


PAGE 3-A

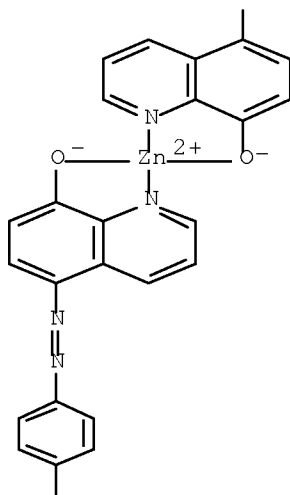


RN 769935-95-7 HCAPLUS
 CN Zinc, bis[5-[[4-(1,1-dimethylethyl)phenyl]azo]-8-quinolinolato-
 κN1,κO8]-, (T-4)-(9CI) (CA INDEX NAME)

PAGE 1-A



PAGE 2-A



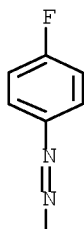
PAGE 3-A



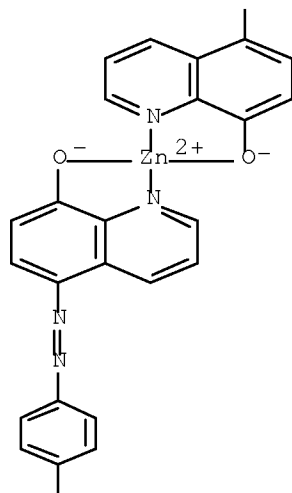
RN 769935-96-8 HCAPLUS

CN Zinc, bis[5-[(4-fluorophenyl)azo]-8-quinolinolato-κN1,κO8]-
 , (T-4)- (9CI) (CA INDEX NAME)

PAGE 1-A



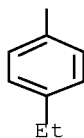
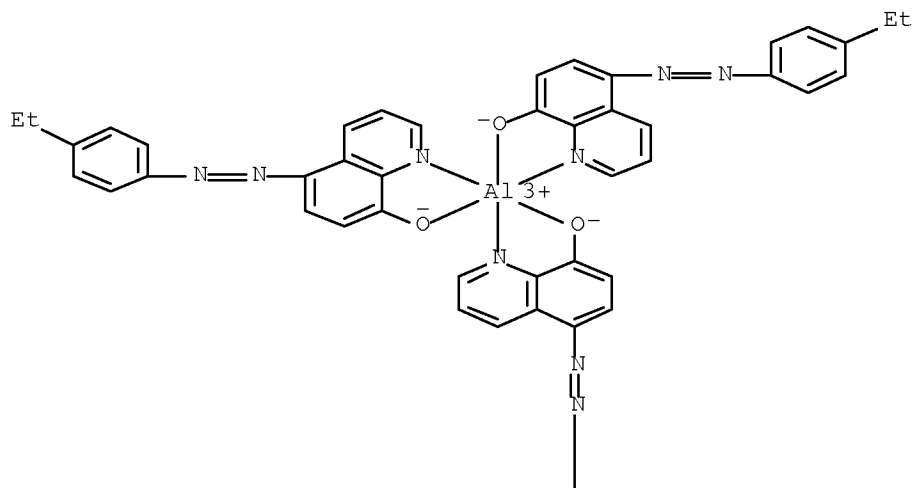
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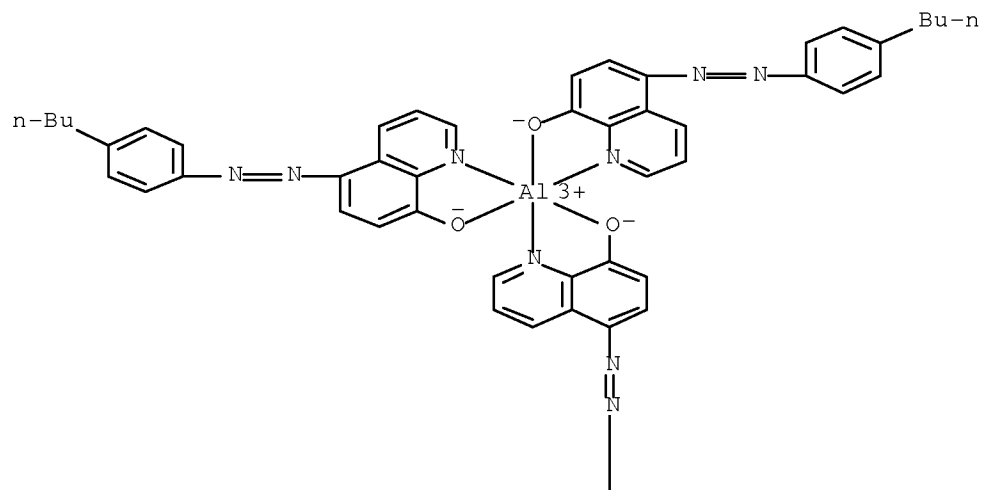
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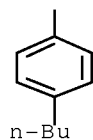
RN 769935-98-0 HCAPLUS
 CN Aluminum, tris[5-[(4-ethylphenyl)azo]-8-quinolinolato-
 κN1,κO8]- (9CI) (CA INDEX NAME)



RN 769935-99-1 HCAPLUS
 CN Aluminum, tris[5-[(4-butylphenyl)azo]-8-quinolinolato-
 κN1,κO8]- (9CI) (CA INDEX NAME)

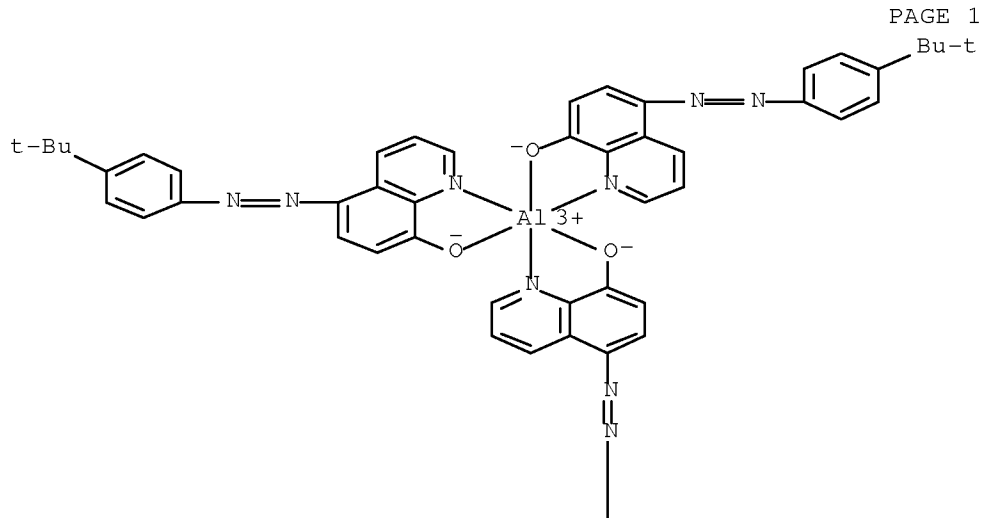


PAGE 2-A

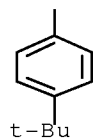


RN 769936-00-7 HCAPLUS
 CN Aluminum, tris[5-[[4-(1,1-dimethylethyl)phenyl]azo]-8-quinolinolato- κ N1, κ O8]- (9CI) (CA INDEX NAME)

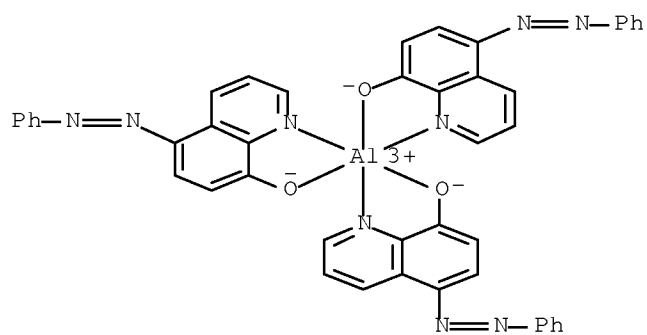
PAGE 1-A



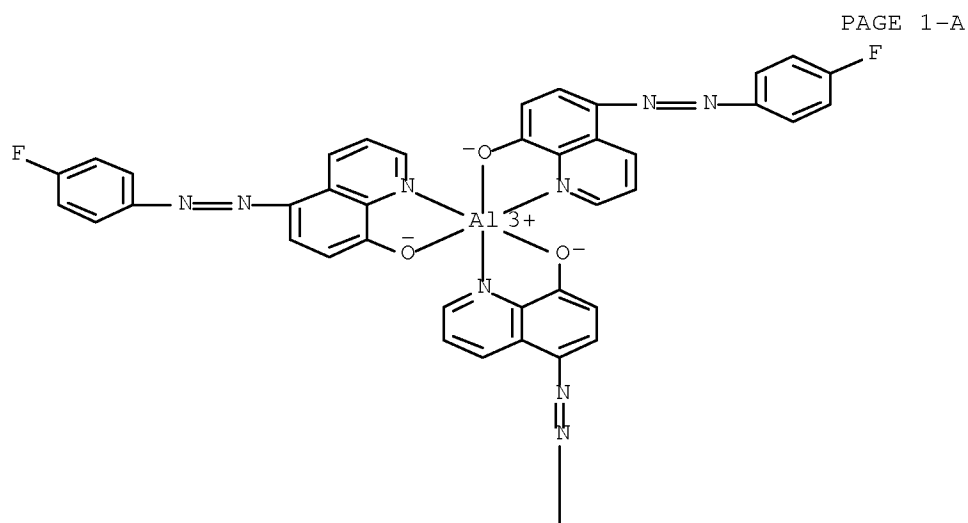
PAGE 2-A



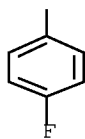
RN 769936-01-8 HCAPLUS
 CN Aluminum, tris[5-(phenylazo)-8-quinolinolato- κ N1, κ O8]- (9CI) (CA INDEX NAME)



RN 769936-02-9 HCAPLUS
 CN Aluminum, tris[5-[(4-fluorophenyl)azo]-8-quinolinolato-
 κN1,κO8]- (9CI) (CA INDEX NAME)



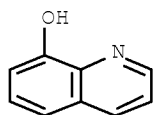
PAGE 1-A



PAGE 2-A

IT 148-24-3, 8-Hydroxyquinoline, reactions
 (reactant for preparation of phenylazohydroxyquinolines)

RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



CC 78-7 (Inorganic Chemicals and Reactions)
 Section cross-reference(s): 27, 65, 72, 73, 75
 IT 769936-04-1
 (cyclic voltammetry and luminescence spectra of)
 IT 769935-97-9P
 (preparation and cyclic voltammetry and fluorescence of)
 IT 14708-01-1P 769935-93-5P 769935-94-6P
 769935-95-7P 769935-96-8P 769935-98-0P
 769935-99-1P 769936-00-7P 769936-01-8P
 769936-02-9P
 (preparation and cyclic voltammetry of)
 IT 148-24-3, 8-Hydroxyquinoline, reactions 371-40-4,
 4-Fluoroaniline 769-92-6, 4-tert-Butylaniline
 (reactant for preparation of phenylazohydroxyquinolines)
 OS.CITING REF COUNT: 4 THERE ARE 4 CAPLUS RECORDS THAT CITE THIS
 RECORD (4 CITINGS)
 REFERENCE COUNT: 48 THERE ARE 48 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

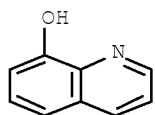
L62 ANSWER 25 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2004:528452 HCAPLUS Full-text
 DOCUMENT NUMBER: 141:284916
 TITLE: Solution-Processible Small Molecular Organic
 Light-Emitting Diode Material
 and Devices Based on the Substituted Aluminum
 Quinolate
 AUTHOR(S): Cheng, Jung-An; Chen, Chin H.; Liao, Chi Hung
 CORPORATE SOURCE: Department of Applied Chemistry and Display
 Institute, Microelectronics and Information System
 Research Center, National Chiao Tung University,
 Hsinchu, 30050, Taiwan
 SOURCE: Chemistry of Materials (2004), 16(15),
 2862-2868
 CODEN: CMATEX; ISSN: 0897-4756
 PUBLISHER: American Chemical Society
 DOCUMENT TYPE: Journal
 LANGUAGE: English
 ED Entered STN: 02 Jul 2004
 AB We have discovered a new type of small mol. host material based on
 aluminum(III) 8-hydroxyquinolates, Al(Saq)3, which was synthesized with three
 5-(N-ethylanilinesulfonamide)-8-quinolinoline as bidentate ligands. By X-ray
 diffraction crystallog. anal., the crystals of meridional Al(Saq)3 are
 monoclinic, space group P21/c, a = 17.952(3) Å, b = 17.716(3) Å, c = 17.080(3)
 Å, β = 99.895(4)°. Its peak photoluminescence in solid phase appears at 488
 nm. Its LUMO/HOMO (-3.13/-6.04 eV) and optical band gap (Eg 2.91 eV) were
 determined by cyclic voltammetry. In solid thin film morphol. investigation,

it shows good thermal properties and high quantum efficiency. When doped with 0.7 weight % of the high fluorescent green dopant 10-(2-benzothiazolyl)-1,1,7,7-tetramethyl-2,3,6,7-tetrahydro-1H,5H,11H-benzo-[l]pyrano[6,7,8-ij]quinolizin-11-one (C-545T), energy transfer from Al(Saq)3 to dopant will occur and high green light emission can be achieved. For fabrication of OLEDs using spin-coating techniques, its electroluminescence is at 1931 CIE_{x,y} (0.21, 0.41).

IT 97-93-8, Triethylaluminum, reactions 148-24-3,
8-Hydroxyquinoline, reactions
(synthesis, structure and optical and thermal properties of
Al(Saq)3 electroluminescent material and devices based on
Al(Saq)3)
RN 97-93-8 HCAPLUS
CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS
CN 8-Quinolinol (CA INDEX NAME)



CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
Section cross-reference(s): 76, 78
ST electroluminescent device aluminum ethylanilinesulfonamide
quinolate photoluminescence band gap structure
IT LUMO (molecular orbital)
(HOMO gap; of Al(Saq)3 electroluminescent material)
IT HOMO (molecular orbital)
(LUMO gap; of Al(Saq)3 electroluminescent material)
IT UV and visible spectra
(absorption; of Al(Saq)3 electroluminescent material)
IT Annealing
(effect on photoluminescence; synthesis, structure and optical and thermal properties of Al(Saq)3 electroluminescent material and devices based on Al(Saq)3)
IT Luminescent substances
(electroluminescent; synthesis, structure, optical and thermal properties of Al(Saq)3 electroluminescent material and devices based on Al(Saq)3)
IT Bond angle
Bond length
Crystal structure
Molecular structure
Surface structure
Thermal stability

X-ray diffraction
 (of Al(Saq)3 electroluminescent material)

IT Band gap
 (optical; of Al(Saq)3 electroluminescent material)

IT Electroluminescent devices
 Energy transfer
 Luminescence, electroluminescence
 (synthesis, structure and optical and thermal properties of
 Al(Saq)3 electroluminescent material and devices based on
 Al(Saq)3)

IT Electric current-potential relationship
 (synthesis, structure, optical and thermal properties of Al(Saq)3
 electroluminescent material and devices based on Al(Saq)3)

IT Luminescence
 (visible; of Al(Saq)3 electroluminescent material)

IT 25067-59-8, PVK
 (PVK; synthesis, structure, optical and thermal properties of
 Al(Saq)3 electroluminescent material and devices based on
 Al(Saq)3)

IT 9003-53-6D, sulfonated
 (dopant for PEDOT; synthesis, structure and optical and thermal
 properties of Al(Saq)3 electroluminescent material and
 devices based on Al(Saq)3)

IT 126213-51-2
 (doped with PSS; synthesis, structure and optical and thermal
 properties of Al(Saq)3 electroluminescent material and
 devices based on Al(Saq)3)

IT 155306-71-1, C 545T
 (fluorescent green dopant; synthesis, structure and optical and
 thermal properties of Al(Saq)3 electroluminescent
 material and devices based on Al(Saq)3)

IT 7429-90-5, Aluminum, uses 7789-24-4, Lithium fluoride LiF, uses
 50926-11-9, Indium tin oxide
 (synthesis, structure and optical and thermal properties of
 Al(Saq)3 electroluminescent material and devices based on
 Al(Saq)3)

IT 757235-20-4P
 (synthesis, structure and optical and thermal properties of
 Al(Saq)3 electroluminescent material and devices based on
 Al(Saq)3)

IT 97-93-8, Triethylaluminum, reactions 103-69-5,
 N-Ethylaniline 148-24-3, 8-Hydroxyquinoline, reactions
 7790-94-5, Chlorosulfonic acid
 (synthesis, structure and optical and thermal properties of
 Al(Saq)3 electroluminescent material and devices based on
 Al(Saq)3)

IT 757231-25-7P
 (synthesis, structure and optical and thermal properties of
 Al(Saq)3 electroluminescent material and devices based on
 Al(Saq)3)

IT 123847-85-8
 (synthesis, structure, optical and thermal properties of Al(Saq)3
 electroluminescent material and devices based on Al(Saq)3)

OS.CITING REF COUNT: 13 THERE ARE 13 CAPLUS RECORDS THAT CITE THIS
 RECORD (13 CITINGS)

REFERENCE COUNT: 16 THERE ARE 16 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

ACCESSION NUMBER: 2004:3688 HCAPLUS Full-text
 DOCUMENT NUMBER: 140:67366
 TITLE: AlRq'2 type aluminum compound and method for
 manufacturing the same and derivative thereof
 INVENTOR(S): Yamamoto, Takakazu; Yamaguchi, Isao; Iijima,
 Takayuki
 PATENT ASSIGNEE(S): Tokyo Institute of Technology, Japan
 SOURCE: U.S. Pat. Appl. Publ., 14 pp.
 CODEN: USXXCO
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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US 20040002578	A1	20040101	US 2003-361575	20030211
			<--	
JP 2004026749	A	20040129	JP 2002-187795	20020627
			<--	
PRIORITY APPLN. INFO.:			JP 2002-187795	A 20020627
			<--	

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

OTHER SOURCE(S): MARPAT 140:67366

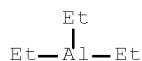
ED Entered STN: 04 Jan 2004

AB By reacting trialkyl aluminum (AlR3) with 2-position substituted 8-quinolinol(q'H) at a mole ratio of 1:2, an AlRq'2 type aluminum compound having a specified structural formula is manufactured. The resulting compound is further reacted with an active hydrogen-containing organic compound to obtain a derivative such as an Alq'2q type derivative, wherein q = 8-quinolinolato ligand and q' = 2-position substituted 8-quinolinolato ligand. Thus, 4.60 mL triethylaluminum and 9.55 g 2-methyl-8-quinolinol were reacted at room temperature for 12 h to give 10.9 g ethylbis(2-methyl-8-quinolinolato)aluminum, which could coordinate a conjugated polymer obtained from 5,7-dibromo-8-tert-butyltrimethylsilyloxyquinoline and 1,4-diethynyl-2,5-didodecyloxybenzene to give a light emitting macromol. suitable for use as an electroluminescence material.

IT 97-93-8, Triethylaluminum, reactions 148-24-3,
 8-Quinolinol, reactions
 (reactant; preparation of alkylidiquinolinol type aluminum compound useful as electroluminescence materials)

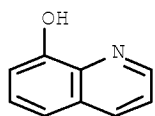
RN 97-93-8 HCAPLUS

CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



IC ICM C08G063-78
 ICS C08G063-87; C07F005-06
 INCL 528205000; 546010000
 CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
 Section cross-reference(s): 78
 ST alkyldiquinolinol aluminum compd prepn electroluminescent material
 IT Luminescent substances
 (electroluminescent; preparation of alkyldiquinolinol type aluminum compound useful as electroluminescence materials)
 IT 535949-58-7P 637772-83-9P 637772-84-0P
 (preparation of alkyldiquinolinol type aluminum compound useful as electroluminescence materials)
 IT 469886-06-4P, Aluminum, bis(2-methyl-8-quinolinolato-κN1,κO8)(8-quinolinolato-κN1,κO8)-, (OC-6-42)-
 (preparation of alkyldiquinolinol type aluminum compound useful as electroluminescence materials)
 IT 468758-29-4P, Aluminum, ethylbis(2-methyl-8-quinolinolato-κN1,κO8)-
 (preparation of alkyldiquinolinol type aluminum compound useful as electroluminescence materials)
 IT 97-93-8, Triethylaluminum, reactions 148-24-3, 8-Quinolinol, reactions 826-81-3, 2-Methyl-8-quinolinol 2446-69-7, 4-Hexylphenol
 (reactant; preparation of alkyldiquinolinol type aluminum compound useful as electroluminescence materials)

L62 ANSWER 27 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2003:1007243 HCAPLUS Full-text
 DOCUMENT NUMBER: 140:51531
 TITLE: Method for the roll-to-roll deposition of an optically transparent and high conductivity metallic thin film
 INVENTOR(S): He, Xiao-Ming; Heydarpour, Ramin
 PATENT ASSIGNEE(S): Avery Dennison Corporation, USA
 SOURCE: PCT Int. Appl., 67 pp.
 CODEN: PIXXD2
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. NUM. COUNT: 2
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
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WO 2003107079	A2	20031224	WO 2003-US18755	20030612
			<--	
WO 2003107079	A9	20040304		
WO 2003107079	A3	20040701		
W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, ES, FI, GB, GD,				

10/594,762

GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ,
LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ,
NO, NZ, OM, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, TJ,
TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW
RW: GH, GM, KE, LS, MW, MZ, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ,
BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK,
EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PT, RO, SE,
SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR,
NE, SN, TD, TG

US 20040001915 A1 20040101 US 2002-172282 20020614

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US 6811815 B2 20041102

AU 2003259035 A1 20031231 AU 2003-259035 20030612

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EP 1534510 A2 20050601 EP 2003-760348 20030612

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R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC,
PT, IE, SI, LT, LV, FI, RO, MK, CY, AL, TR, BG, CZ, EE, HU, SK

PRIORITY APPLN. INFO.: US 2002-172282 A 20020614

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WO 2003-US18755 W 20030612

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ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

ED Entered STN: 26 Dec 2003

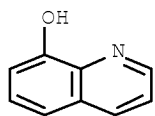
AB The invention relates to a method for the roll-to-roll deposition of an optically transparent and high conductivity metallic thin film, allowing the film to be collected in a continuous roll. The method consists of the steps of (i) providing a flexible plastic substrate; (ii) depositing a multilayered conductive metallic film on the flexible plastic substrate by a thin film deposition technique to form a composite film; and (iii) collecting the composite film in continuous rolls.

IT 148-24-3D, 8-Hydroxyquinoline, metal complexes
2085-33-8D, Alq3, derivs.

(luminescent material; method for roll-to-roll deposition
of optically transparent and high conductivity metallic thin film)

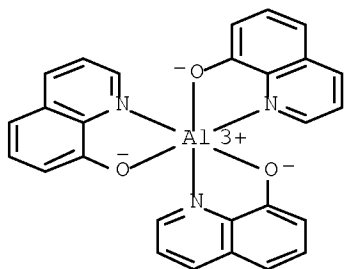
RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



- IC ICM G02F
- CC 76-2 (Electric Phenomena)
Section cross-reference(s): 38, 56, 57, 73, 78
- IT Ketones, uses
(1,3-diketones, metal complexes, luminescent material;
method for roll-to-roll deposition of optically transparent and
high conductivity metallic thin film)
- IT Vapor deposition process
(chemical; method for roll-to-roll deposition of optically transparent
and high conductivity metallic thin film)
- IT Schiff bases
(complexes, luminescent material; method for roll-to-roll
deposition of optically transparent and high conductivity metallic thin
film)
- IT Vapor deposition process
(ion plating; method for roll-to-roll deposition of optically
transparent and high conductivity metallic thin film)
- IT Polyacetylenes, uses
(ladder, luminescent material; method for roll-to-roll
deposition of optically transparent and high conductivity metallic thin
film)
- IT Charge transfer complexes
Organometallic compounds
Poly(arylenealkenylenes)
Polyanilines
Polyphenyls
Rare earth complexes
(luminescent material; method for roll-to-roll deposition
of optically transparent and high conductivity metallic thin film)
- IT Composites
Laser ablation
Luminescent substances
Magnetron sputtering
(method for roll-to-roll deposition of optically transparent and
high conductivity metallic thin film)
- IT Ladder polymers
(polyacetylenes, luminescent material; method for
roll-to-roll deposition of optically transparent and high conductivity
metallic thin film)
- IT 91-22-5D, Quinoline, metal complexes 123-54-6D, Acetylacetone, metal
complexes 148-24-3D, 8-Hydroxyquinoline, metal complexes
2085-33-8D, Alq3, derivs. 7440-31-5D, Tin, tin(IV) complexes
9033-83-4, Poly(phenylene) 17056-99-4D, 5-Hydroxyquinoxaline, metal
complexes 25038-69-1, Poly(phenylacetylene) 25067-59-8,
Poly(N-vinylcarbazole) 25233-30-1, Poly(aniline) 25233-34-5,
Poly(thiophene) 25233-34-5D, Poly(thiophene), 3-alkyl derivs.

10/594,762

26009-24-5, Poly(p-phenylenevinylene) 26009-24-5D,
Poly(p-phenylenevinylene), dialkoxy derivs. 41999-83-1D,
Maleonitriledithiol, metal complexes 95270-88-5, Poly(fluorene)
104934-51-2, Poly(3-octylthiophene)

(luminescent material; method for roll-to-roll deposition
of optically transparent and high conductivity metallic thin film)

REFERENCE COUNT: 1 THERE ARE 1 CITED REFERENCES AVAILABLE FOR
THIS RECORD. ALL CITATIONS AVAILABLE IN THE
RE FORMAT

L62 ANSWER 28 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2003:732139 HCAPLUS Full-text

DOCUMENT NUMBER: 139:365902

TITLE: Immiscible polymers in double spin-coated
electroluminescent devices containing
phenyl-substituted
tris(8-hydroxyquinoline)aluminum derivatives
soluble in a host polymer

AUTHOR(S): Shoji, E.; Miyatake, K.; Hlil, A. R.; Hay, A. S.;
Maindron, T.; Jousseume, V.; Dodelet, J. P.; Tao,
Y.; D'Iorio, M.

CORPORATE SOURCE: Department of Chemistry, McGill University,
Montreal, QC, H3A 2K6, Can.

SOURCE: Journal of Polymer Science, Part A: Polymer
Chemistry (2003), 41(19), 3006-3016
CODEN: JPACEC; ISSN: 0887-624X

PUBLISHER: John Wiley & Sons, Inc.

DOCUMENT TYPE: Journal

LANGUAGE: English

ED Entered STN: 18 Sep 2003

AB Three new phenyl-substituted tris(8-hydroxyquinoline)aluminum (AlQ3) derivs.
have been synthesized:.

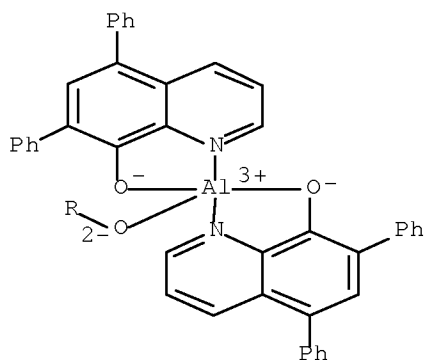
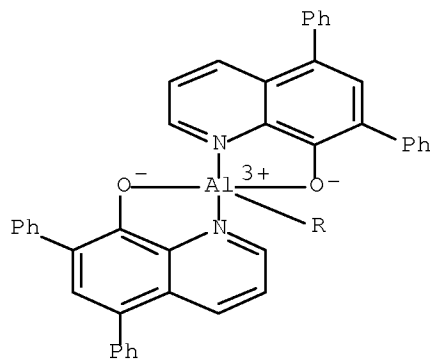
Tris(5-phenyl-8-quinolinolate-N1,O8)aluminum, Tris(5,7-diphenyl-8-
quinolinolate-N1,O8)aluminum, and Tris[5,7-bis(p-fluorophenyl)-8-
quinolinolate-N1,O8]aluminum. These AlQ3 derivs. are easily soluble in common
organic solvents and form solid-phase solns. in a poly(aryl ether ketone) host
polymer (A 435). These interesting properties allow the use of soluble AlQ3
derivs. in double spin-coated organic light-emitting devices of the type
ITO/NPB-QP/A 435 + 50 wt% soluble AlQ3 derivative/Mg, where NPB-QP is a hole-
transporting polymer insol. in toluene, the solvent for A 435. Typical double
spin-coated organic layer devices are characterized by an emission at 530-539
nm, a threshold voltage of 6-9 V, and a maximum luminance of 1800-4000 cd/m2
at 21-25 V.

IT 620987-22-6P

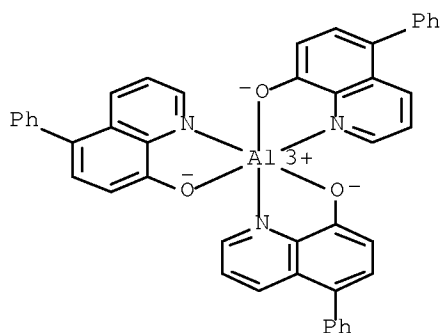
(preparation and properties of Ph-substituted
tris(8-hydroxyquinoline)aluminum derivs. used in double spin-
coated electroluminescent devices with specially
designed hole-transporting polymer)

RN 620987-22-6 HCAPLUS

CN Aluminum, tetrakis(5,7-diphenyl-8-quinolinolato-κN1,κO8)-
μ-oxodi- (CA INDEX NAME)

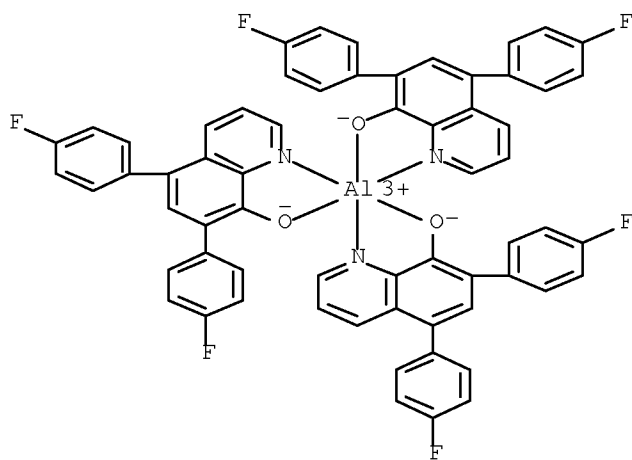


IT 213620-77-0P 269407-70-7P 362623-43-6P
 (preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs.
 used in double spin-coated electroluminescent
 devices with specially designed hole-transporting
 polymer)
 RN 213620-77-0 HCAPLUS
 CN Aluminum, tris(5-phenyl-8-quinolinolato-κN1,κO8)- (CA
 INDEX NAME)



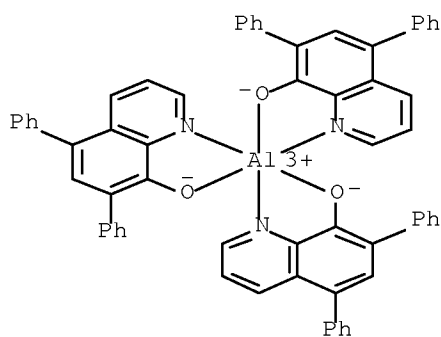
RN 269407-70-7 HCAPLUS

CN Aluminum, tris[5,7-bis(4-fluorophenyl)-8-quinolinolato-κN1,κO8]- (CA INDEX NAME)

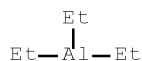


RN 362623-43-6 HCAPLUS

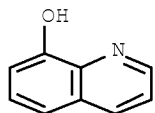
CN Aluminum, tris(5,7-diphenyl-8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



IT 97-93-8, Triethylaluminum, reactions 148-24-3,
 8-Hydroxyquinoline, reactions
 (starting material; preparation of Ph-substituted
 tris(8-hydroxyquinoline)aluminum derivs. used in double spin-
 coated electroluminescent devices with specially
 designed hole-transporting polymer)
 RN 97-93-8 HCAPLUS
 CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



CC 38-3 (Plastics Fabrication and Uses)
 Section cross-reference(s): 29, 73, 76
 ST hydroxyquinoline aluminum phenyl substituted
 electroluminescence host polymer immiscibility; light
 emitting device polyether polyketone host hydroxyquinoline
 aluminum deriv
 IT Polysulfones, uses
 (polyamine-polyether-, aromatic, hole-transporting polymer;
 preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs.
 used in double spin-coated electroluminescent
 devices with specially designed hole-transporting
 polymer)
 IT Polyethers, uses
 (polyamine-polysulfone-, aromatic, hole-transporting
 polymer; preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum
 derivs. used in double spin-coated
 electroluminescent devices with specially designed hole-
 transporting polymer)
 IT Polyketones
 (polyether-, aromatic, host polymer; preparation of Ph-substituted
 tris(8-hydroxyquinoline)aluminum derivs. used in double spin-
 coated electroluminescent devices with specially
 designed hole-transporting polymer)
 IT Polyamines
 (polyether-polysulfone-, aromatic, hole-transporting
 polymer; preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum
 derivs. used in double spin-coated
 electroluminescent devices with specially designed hole-
 transporting polymer)

- IT Polyethers, uses
(polyketone-, aromatic, host polymer; preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs. used in double spin-coated electroluminescent devices with specially designed hole-transporting polymer)
- IT Band gap
Electric current
Electroluminescent devices
Emissivity
Fluorescence
Glass transition temperature
Luminescence, electroluminescence
Solubility
Threshold potential
(preparation and properties of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs. used in double spin-coated electroluminescent devices with specially designed hole-transporting polymer)
- IT 132980-80-4, A 435 (Polymer)
(A 435, host polymer; preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs. used in double spin-coated electroluminescent devices with specially designed hole-transporting polymer)
- IT 123847-85-8D, NPB, polyether-polysulfones
(hole-transporting polymer; preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs. used in double spin-coated electroluminescent devices with specially designed hole-transporting polymer)
- IT 1198-14-7P, 5-Bromo-8-hydroxyquinoline 15657-87-1P 84165-50-4P
202259-06-1P 202259-09-4P 620987-08-8P 620987-09-9P
620987-10-2P 620987-11-3P
(intermediate; preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs. used in double spin-coated electroluminescent devices with specially designed hole-transporting polymer)
- IT 620987-22-6P
(preparation and properties of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs. used in double spin-coated electroluminescent devices with specially designed hole-transporting polymer)
- IT 7439-95-4, Magnesium, uses 50926-11-9, Indium tin oxide
(preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs. used in double spin-coated electroluminescent devices with specially designed hole-transporting polymer)
- IT 213620-77-0P 269407-70-7P 362623-43-6P
(preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs. used in double spin-coated electroluminescent devices with specially designed hole-transporting polymer)
- IT 97-93-8, Triethylaluminum, reactions 98-80-6,
Phenylboronic acid 100-44-7, Benzyl chloride, reactions
148-24-3, 8-Hydroxyquinoline, reactions 521-74-4
1765-93-1, p-Fluorophenylboronic acid
(starting material; preparation of Ph-substituted tris(8-hydroxyquinoline)aluminum derivs. used in double spin-coated electroluminescent devices with specially designed hole-transporting polymer)

OS.CITING REF COUNT: 6 THERE ARE 6 CAPLUS RECORDS THAT CITE THIS
RECORD (7 CITINGS)

REFERENCE COUNT: 42 THERE ARE 42 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L62 ANSWER 29 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2002:872172 HCAPLUS Full-text

DOCUMENT NUMBER: 138:212400

TITLE: Novel bis(8-hydroxyquinoline)phenolato-aluminum complexes for organic light-emitting diodes

AUTHOR(S): Wang, Guang; Liang, Fushun; Xie, Zhiyuan; Su, Guangping; Wang, Lixiang; Jing, Xiabin; Wang, Fosong

CORPORATE SOURCE: Changchun Institute of Applied Chemistry, The State Key Laboratory of Polymer Physics and Chemistry, Chinese Academy of Sciences, Changchun, 130022, Peop. Rep. China

SOURCE: Synthetic Metals (2002), 131(1-3), 1-5

CODEN: SYMEDZ; ISSN: 0379-6779

PUBLISHER: Elsevier Science B.V.

DOCUMENT TYPE: Journal

LANGUAGE: English

ED Entered STN: 18 Nov 2002

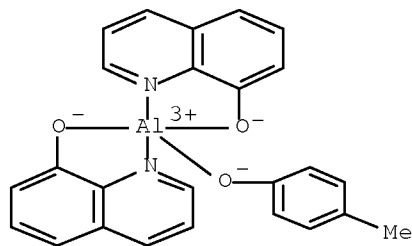
AB Emitting Al complexes containing 2 8-hydroxyquinoline ligands (q) and a phenolato ligand (p) were synthesized and characterized. Double layer organic light-emitting diodes (OLEDs) were fabricated using these complexes as luminescent layers, and strong electroluminescence (EL) was observed. Their emitting wavelengths were mainly determined by the 1st ligands (q). Cyclic voltammograms revealed a partially irreversible n-doping process and indicated that these complexes show excellent electron-transporting ability.

IT 146734-96-5P 224785-36-8P 444716-92-1P
500298-25-9P

((8-hydroxyquinoline)phenolato-aluminum complexes for organic LEDs)

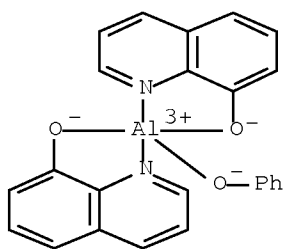
RN 146734-96-5 HCAPLUS

CN Aluminum, (4-methylphenolato)bis(8-quinolinolato-N1,O8)- (9CI) (CA INDEX NAME)

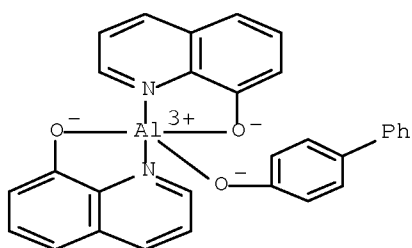


RN 224785-36-8 HCAPLUS

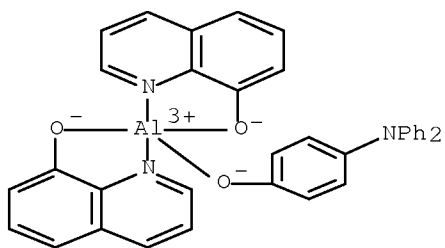
CN Aluminum, phenoxybis(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



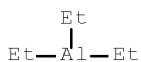
RN 444716-92-1 HCAPLUS
 CN Aluminum, [[1,1'-biphenyl]-4-olato]bis(8-quinolinolato-
 κN1,κO8)- (CA INDEX NAME)



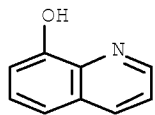
RN 500298-25-9 HCAPLUS
 CN Aluminum, [4-(diphenylamino)phenolato-κO]bis(8-quinolinolato-
 κN1,κO8)- (CA INDEX NAME)



IT 97-93-8, Triethylaluminum, uses 148-24-3,
 8-Hydroxyquinoline, uses
 ((8-hydroxyquinoline)phenolato-aluminum complexes for organic
 LEDs synthesized using)
 RN 97-93-8 HCAPLUS
 CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other
 Related Properties)
 Section cross-reference(s): 72, 76, 77

ST LED hydroxyquinoline phenolato aluminum deriv complex;
 cyclic voltammetry hydroxyquinoline phenolato aluminum deriv complex
 LED; electroluminescence hydroxyquinoline phenolato
 aluminum deriv complex LED; current voltage hydroxyquinoline
 phenolato aluminum deriv complex LED; NMR spectra
 hydroxyquinoline phenolato aluminum deriv complex LED;
 luminescence hydroxyquinoline phenolato aluminum deriv complex
 LED

IT Electroluminescent devices
 ((8-hydroxyquinoline)phenolato-aluminum complexes for organic
 LEDs)

IT Cyclic voltammetry
 Luminescence
 NMR (nuclear magnetic resonance)
 (of (8-hydroxyquinoline)phenolato-aluminum complexes for organic
 LEDs)

IT Electric current-potential relationship
 Electric potential
 Luminescence, electroluminescence
 (of (8-hydroxyquinoline)phenolato-aluminum complexes in organic
 LEDs)

IT 146734-96-5P 224785-36-8P 444716-92-1P
 500298-25-9P
 ((8-hydroxyquinoline)phenolato-aluminum complexes for organic
 LEDs)

IT 50926-11-9, ITO 123847-85-8, Npb
 ((8-hydroxyquinoline)phenolato-aluminum complexes for organic
 LEDs containing)

IT 92-69-3, p-Phenylphenol 97-93-8, Triethylaluminum, uses
 106-44-5, p-Methylphenol, uses 108-95-2, Phenol, uses
 148-24-3, 8-Hydroxyquinoline, uses 25069-86-7, Phenol,
 4-diphenylamino-
 ((8-hydroxyquinoline)phenolato-aluminum complexes for organic
 LEDs synthesized using)

OS.CITING REF COUNT: 18 THERE ARE 18 CAPLUS RECORDS THAT CITE THIS
 RECORD (18 CITINGS)

REFERENCE COUNT: 10 THERE ARE 10 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 30 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2002:626736 HCAPLUS Full-text
 DOCUMENT NUMBER: 137:338348

TITLE: Synthesis of ALQ3-containing polymers using ring-opening metathesis polymerization

AUTHOR(S): Meyers, Amy; Weck, Marcus

CORPORATE SOURCE: Sch. Chem. Biochemistry, Georgia Inst. Technology, Atlanta, GA, 30332, USA

SOURCE: Polymer Preprints (American Chemical Society, Division of Polymer Chemistry) (2002), 43(2), 1134
CODEN: ACPPAY; ISSN: 0032-3934

PUBLISHER: American Chemical Society, Division of Polymer Chemistry

DOCUMENT TYPE: Journal; (computer optical disk)

LANGUAGE: English

ED Entered STN: 20 Aug 2002

AB A functionalized norbornene unit, containing the attached Alq3 group, was polymerized using ring-opening metathesis. An 8-hydroxyquinoline mol. was attached to norbornene; self-assembly of the Alq2 component gave monomer which was then polymerized, resulting in a polymer containing the Alq3 pendants. The UV-visible spectra of both the monomer and polymer show similar absorption peaks as Alq3. Both the monomer and polymer also emitted light at the same wavelength (524 nm) as Alq3. The attachment of the Alq3-pendant group onto a polymer backbone will allow for easy fabrication of electroluminescent devices, such as light-emitting diodes.

IT 97-93-8, Triethylaluminum, reactions 148-24-3, 8-Hydroxyquinoline, reactions
(preparation of luminescent aluminum-tris(hydroxyquinoline)-pendant polynorbornene by ring-opening metathesis polymerization of prepared monomer)

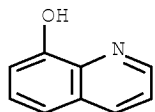
RN 97-93-8 HCAPLUS

CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



CC 35-7 (Chemistry of Synthetic High Polymers)
Section cross-reference(s): 36, 73

ST hydroxyquinoline norbornene carboxylate monomer prepn ring opening
polymn; ring opening metathesis polymn Alq3 pendant polymer prepn;
luminescence self assembly Alq3 pendant polymer

IT Polymerization
(metathetic, ring-opening; preparation of luminescent aluminum-tris(hydroxyquinoline)-pendant polynorbornene by ring-opening metathesis polymerization of prepared monomer)

IT Luminescence
 Self-assembly
 UV and visible spectra
 (preparation of luminescent
 aluminum-tris(hydroxyquinoline)-pendant polynorbornene by
 ring-opening metathesis polymerization of prepared monomer)

IT 474096-45-2P
 (Alq3 monomer; preparation of luminescent
 aluminum-tris(hydroxyquinoline)-pendant polynorbornene by
 ring-opening metathesis polymerization of prepared monomer)

IT 246047-72-3
 (ROMP catalyst; preparation of luminescent
 aluminum-tris(hydroxyquinoline)-pendant polynorbornene by
 ring-opening metathesis polymerization of prepared monomer)

IT 474096-44-1P
 (intermediate; preparation of luminescent
 aluminum-tris(hydroxyquinoline)-pendant polynorbornene by
 ring-opening metathesis polymerization of prepared monomer)

IT 474096-46-3P
 (preparation of luminescent
 aluminum-tris(hydroxyquinoline)-pendant polynorbornene by
 ring-opening metathesis polymerization of prepared monomer)

IT 97-93-8, Triethylaluminum, reactions 148-24-3,
 8-Hydroxyquinoline, reactions 27063-48-5
 (preparation of luminescent
 aluminum-tris(hydroxyquinoline)-pendant polynorbornene by
 ring-opening metathesis polymerization of prepared monomer)

REFERENCE COUNT: 17 THERE ARE 17 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 31 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2002:309105 HCAPLUS Full-text

DOCUMENT NUMBER: 137:207881

TITLE: Red light-emitting material
 for organic electroluminescence

AUTHOR(S): Shao, Yan; Liu, Yuhong; Qiu, Yong

CORPORATE SOURCE: Department of Chemistry, Tsinghua University,
 Beijing, 100084, Peop. Rep. China

SOURCE: Gongneng Cailiao (2001), 32(6), 662-663,
 666

CODEN: GOCAEA; ISSN: 1001-9731

PUBLISHER: Gongneng Cailiao Bianjibu

DOCUMENT TYPE: Journal

LANGUAGE: Chinese

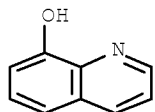
ED Entered STN: 25 Apr 2002

AB The red light-emitting material used in organic electroluminescence, an Al
 complex, (2,2'- dihydroxyazobenzene)-(8-quinolinoato) Al (Al(azb-q)), was
 prepared by using AlCl₃.6H₂O, 2,2'-dihydroxyazobenzene, and 8-
 hydroxyquinoline. The material had high decomposition temperature of 200° and
 electron transport ability. The maximum wavelength of the EL emission of
 Al(azb-q) was at 635 nm. The color position in the color coordinates system
 showed a strong potential as a red light- emitting material for organic
 electroluminescence.

IT 148-24-3, 8-Hydroxyquinoline, uses 7784-13-6,
 Aluminum chloride hexahydrate
 (in preparation of (2,2'-Dihydroxyazobenzene)(8-quinolinoato)aluminum)

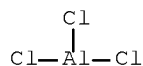
RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



RN 7784-13-6 HCAPLUS

CN Aluminum chloride (AlCl₃), hydrate (1:6) (CA INDEX NAME)



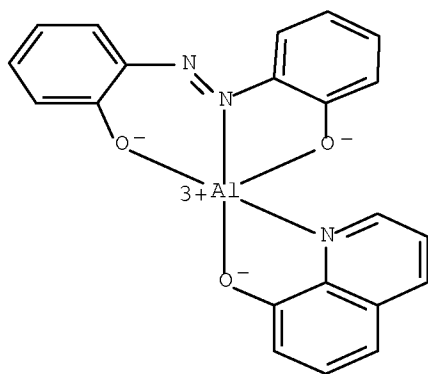
●₆ H₂O

IT 351530-99-9P

(red light-emitting material for organic electroluminescence)

RN 351530-99-9 HCAPLUS

CN Aluminum, [[2,2'-(azo-κN)-bis[phenolato-κO]](2-)](8-quinolinolato-κN1,κO8)- (9CI) (CA INDEX NAME)



CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 74, 78

ST red light emitting material org
electroluminescence prepn; hydroxyazobenzene quinolinoato
aluminum

IT Luminescence, electroluminescence

(red; of (2,2'-Dihydroxyazobenzene)(8-quinolinoato)aluminum)

IT 148-24-3, 8-Hydroxyquinoline, uses 2050-14-8,
2,2'-Dihydroxyazobenzene 7784-13-6, Aluminum chloride
hexahydrate

(in preparation of (2,2'-Dihydroxyazobenzene)(8-quinolinoato)aluminum)

IT 351530-99-9P

(red light-emitting material for organic
electroluminescence)OS.CITING REF COUNT: 1 THERE ARE 1 CAPLUS RECORDS THAT CITE THIS
RECORD (1 CITINGS)

L62 ANSWER 32 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2001:376188 HCAPLUS Full-text

DOCUMENT NUMBER: 135:146235

TITLE: Synthesis and luminescence behaviors of
aluminum complex with mixed ligandsAUTHOR(S): Jang, H.; Do, L.-M.; Kim, Y.; Gon Kim, J.; Zyung,
T.; Do, Y.CORPORATE SOURCE: Department of Chemistry, School of Molecular
Science, Taejon, 305-600, S. KoreaSOURCE: Synthetic Metals (2001), 121(1-3),
1669-1670

CODEN: SYMEDZ; ISSN: 0379-6779

PUBLISHER: Elsevier Science S.A.

DOCUMENT TYPE: Journal

LANGUAGE: English

OTHER SOURCE(S): CASREACT 135:146235

ED Entered STN: 25 May 2001

AB A novel mixed ligand complex, AlQ(ClQ)₂ (HQ = 8-quinolinol, HClQ = 5,7-
dichloro-8-quinolinol) was synthesized and characterized. An organic
electroluminescent (EL) deviceITO/TPD/AlQ(ClQ)₂/LiF/Al (ITO = In-Sn oxide, TPD = N,N'-diphenyl-N,N'-bis(3-
methylphenyl)-1,1'-biphenyl-4,4'-diamine) was employed to study their EL
properties. The EL device exhibits green light with maximum luminescence of
780 cd/m² at 6.7 V.IT 97-93-8, Triethylaluminum, reactions 148-24-3,
8-Quinolinol, reactions(reactant for preparation of aluminum quinolinolate
dichloroquinolinolate complex)

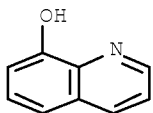
RN 97-93-8 HCAPLUS

CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS

CN 8-Quinolinol (CA INDEX NAME)



CC 78-7 (Inorganic Chemicals and Reactions)

ST aluminum quinolinol chloroquinolinol complex prepn
luminescence

IT Electroluminescent devices
(green-emitting; using aluminum quinolinolate dichloroquinolinolate complex)

IT luminescence
(of aluminum quinolinolate dichloroquinolinolate complex)

IT 352004-29-6P
(preparation and luminescence and electroluminescent device using)

IT 97-93-8, Triethylaluminum, reactions 148-24-3,
8-Quinolinol, reactions 773-76-2, 5,7-Dichloro-8-quinolinol
(reactant for preparation of aluminum quinolinolate dichloroquinolinolate complex)

OS.CITING REF COUNT: 13 THERE ARE 13 CAPLUS RECORDS THAT CITE THIS RECORD (13 CITINGS)

REFERENCE COUNT: 5 THERE ARE 5 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L62 ANSWER 33 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2001:185142 HCAPLUS Full-text

DOCUMENT NUMBER: 134:246046

TITLE: Efficient electron-injection for organic electroluminescent devices

INVENTOR(S): Madathil, Joseph K.; Mason, Max Garrett; Tang, Ching Wan

PATENT ASSIGNEE(S): Eastman Kodak Company, USA

SOURCE: Eur. Pat. Appl., 12 pp.

CODEN: EPXXDW

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO. -----	KIND ----	DATE -----	APPLICATION NO. -----	DATE -----
EP 1083612	A2	20010314	EP 2000-202921	20000821
			<--	
EP 1083612	A3	20040102		
R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT, IE, SI, LT, LV, FI, RO				
US 6278236	B1	20010821	US 1999-387402	19990902
			<--	
JP 2001085165	A	20010330	JP 2000-267679	20000904
			<--	
PRIORITY APPLN. INFO.:			US 1999-387402	A 19990902
			<--	

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

ED Entered STN: 16 Mar 2001

AB An organic electroluminescent (EL) device having a layered structure, including an anode; an organic hole-transport layer in contact with the anode; an organic emitting layer having 1 surface thereof in contact with the hole-transport layer; an organic electron-transport layer in contact with a second surface of the emitting layer; an electron-injecting layer in contact with the electron-transport layer; and a cathode in contact with the electron-injecting layer, in which the electron-injecting layer includes Al and ≥ 1 alkali halide or ≥ 1 alkaline earth halide.

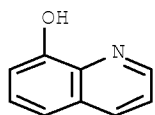
IT 7429-90-5, Aluminum, processes
(electron-injection layer; efficient electron-injection layers for organic electroluminescent devices)

RN 7429-90-5 HCAPLUS

CN Aluminum (CA INDEX NAME)

Al

IT 148-24-3, 8-Quinolinol, processes
 (emitting layer; efficient electron-injection layers for organic
 electroluminescent devices)
 RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



IT 37275-76-6, Aluminum Zinc oxide 117944-65-7,
 Indium Zinc oxide
 (light transmissive anode; efficient electron-injection layers for
 organic electroluminescent devices)
 RN 37275-76-6 HCAPLUS
 CN Aluminum zinc oxide (CA INDEX NAME)

Component	Ratio	Component
		Registry Number
=====	=====	=====
O	x	17778-80-2
Zn	x	7440-66-6
Al	x	7429-90-5

RN 117944-65-7 HCAPLUS
 CN Indium zinc oxide (CA INDEX NAME)

Component	Ratio	Component
		Registry Number
=====	=====	=====
O	x	17778-80-2
In	x	7440-74-6
Zn	x	7440-66-6

IC ICM H01L051-20
 CC 76-3 (Electric Phenomena)
 Section cross-reference(s): 74, 75
 ST efficient electron injection org electroluminescent device
 IT Electron transport
 Electron-hole recombination
 Hole transport
 (efficient electron-injection layers for organic
 electroluminescent devices)
 IT Transparent films
 (elec. conductive, anode; efficient electron-injection layers for
 organic electroluminescent devices)

IT Alkali metal fluorides
 Alkaline earth fluorides
 (electron-injection layer; efficient electron-injection layers for organic electroluminescent devices)

IT Conduction electrons
 (electron-injection; efficient electron-injection layers for organic electroluminescent devices)

IT Electric conductors
 (films, transparent, anode; efficient electron-injection layers for organic electroluminescent devices)

IT Electroluminescent devices
 (organic; efficient electron-injection layers for organic electroluminescent devices)

IT Glass, uses
 Plastics, uses
 (substrate; efficient electron-injection layers for organic electroluminescent devices)

IT Vapor deposition process
 (vacuum; efficient electron-injection layers for organic electroluminescent devices)

IT 7429-90-5, Aluminum, processes
 (electron-injection layer; efficient electron-injection layers for organic electroluminescent devices)

IT 7681-49-4, Sodium fluoride, processes 7783-40-6, Magnesium fluoride
 7783-48-4, Strontium fluoride 7787-32-8, Barium fluoride
 7789-23-3, Potassium fluoride 7789-24-4, Lithium fluoride, processes
 7789-75-5, Calcium fluoride, processes 13400-13-0, Cesium fluoride
 13446-74-7, Rubidium fluoride
 (electron-injection layers; efficient electron-injection layers for organic electroluminescent devices)

IT 148-24-3, 8-Quinolinol, processes
 (emitting layer; efficient electron-injection layers for organic electroluminescent devices)

IT 1332-29-2, Tin oxide 12640-79-8, Nickel tungsten oxide
 37275-76-6, Aluminum Zinc oxide 50926-11-9, Indium-tin-oxide
 56997-34-3, Cadmium tin oxide 117944-65-7, Indium Zinc
 oxide 158346-28-2, Indium Magnesium oxide
 (light transmissive anode; efficient electron-injection layers for organic electroluminescent devices)

IT 14808-60-7, Quartz, uses
 (substrate; efficient electron-injection layers for organic electroluminescent devices)

OS.CITING REF COUNT: 6 THERE ARE 6 CAPLUS RECORDS THAT CITE THIS
 RECORD (6 CITINGS)

REFERENCE COUNT: 1 THERE ARE 1 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 34 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2001:6947 HCAPLUS Full-text

DOCUMENT NUMBER: 134:185686

TITLE: Material transport regimes and mechanisms for
 growth of molecular organic thin films using
 low-pressure organic vapor phase deposition

AUTHOR(S): Shtein, Max; Gossenberger, Herman F.; Benziger,
 Jay B.; Forrest, Stephen R.

CORPORATE SOURCE: Center for Photonics and Optoelectronic Materials
 and Department of Chemical Engineering, Princeton
 University, Princeton, NJ, 08544, USA

SOURCE: Journal of Applied Physics (2001),

89(2), 1470-1476

CODEN: JAPIAU; ISSN: 0021-8979

PUBLISHER: American Institute of Physics

DOCUMENT TYPE: Journal

LANGUAGE: English

ED Entered STN: 04 Jan 2001

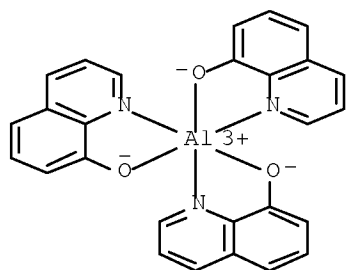
AB The authors determine the phys. mechanisms controlling the growth of amorphous organic thin films by the process of low-pressure organic vapor phase deposition (LP-OVPD). In LP-OVPD, multiple host and dopant mol. sources are introduced into a hot wall reactor via several injection barrels using an inert carrier gas, allowing for controlled film growth rates exceeding 10 Å/s. The temperature and carrier flow rate for each source can be independently regulated, allowing considerable control over dopant concentration, deposition rate, and thickness uniformity of the thin films. The rate of film deposition is limited either by the rate of condensation on the substrate or by the rate of supply from the source. The source-limited regime can be further classified into equilibrium or kinetically limited evaporation, coupled to convection- or diffusion-limited deposition. Models are developed to relate the rate of film growth to source and substrate temperature, and carrier gas flow rate. These models characterize and predict the performance of the LP-OVPD system used to grow high performance organic light emitting devices.

IT 2085-33-8, Tris(8-hydroxyquinoline)aluminum

(material transport regimes and mechanisms for growth of mol. organic thin films using low-pressure organic vapor phase deposition)

RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

Section cross-reference(s): 74, 75, 76

IT Convective flow

Dopants

Electroluminescent devices

Flow

Fluorescent dyes

Simulation and Modeling, physicochemical

Thickness

Vapor deposition process

(material transport regimes and mechanisms for growth of mol. organic thin films using low-pressure organic vapor phase deposition)

IT 147-14-8, Copper phthalocyanine 2085-33-8,

Tris(8-hydroxyquinoline)aluminum 31248-39-2, Platinum

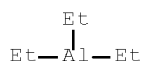
octaethylporphyrin 58328-31-7, 4,4'-N,N'-Dicarbazolylbiphenyl

94928-86-6 123847-85-8, α-NPD

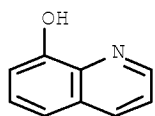
(material transport regimes and mechanisms for growth of mol. organic

thin films using low-pressure organic vapor phase deposition)
 OS.CITING REF COUNT: 51 THERE ARE 51 CAPLUS RECORDS THAT CITE THIS
 RECORD (51 CITINGS)
 REFERENCE COUNT: 20 THERE ARE 20 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 35 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 2000:536215 HCAPLUS Full-text
 DOCUMENT NUMBER: 133:238413
 TITLE: Synthesis and characterization of a novel
 AlQ3-containing polymer
 AUTHOR(S): Lu, Jianping; Hlil, Antisar R.; Meng, Yuezhong;
 Hay, Allan S.; Tao, Ye; D'Iorio, Marie; Maindron,
 Tony; Dodelet, Jean-Pol
 CORPORATE SOURCE: Department of Chemistry, McGill University,
 Montreal, QC, H3A 2K6, Can.
 SOURCE: Journal of Polymer Science, Part A: Polymer
 Chemistry (2000), 38(16), 2887-2892
 CODEN: JPACEC; ISSN: 0887-624X
 PUBLISHER: John Wiley & Sons, Inc.
 DOCUMENT TYPE: Journal
 LANGUAGE: English
 ED Entered STN: 06 Aug 2000
 AB The synthesis of a tris(8-hydroxyquinoline)aluminum (AlQ3)-containing
 poly(arylene ether) (I) is reported. The presence of AlQ3 pendants in polymer
 I is confirmed by NMR, UV-visible, photoluminescence, and gel permeation
 chromatog. analyses. This is the first report of the attachment of AlQ3
 complexes as side chains to a polymer. Polymer I has a glass-transition
 temperature of 217.8° and is thermally stable with a 5% weight-loss
 temperature greater than 500° under nitrogen, as determined by differential
 scanning calorimetry and thermogravimetric analyses, resp. Polymer I is quite
 soluble in common organic solvents, such as THF, N,N-dimethylacetamide, and
 CHCl3. A composite that is 80 wt % polymer I and 20 wt% AlQ3 forms a
 transparent and tough film when cast from its chloroform solution. The
 application of this AlQ3-containing polymer in light-emitting diodes is under
 investigation.
 IT 97-93-8DP, Triethylaluminum, reaction products with
 poly(arylene ether), aminohydroquinoline, and hydroxyquinoline
 148-24-3DP, 8-Hydroxyquinoline, reaction products with
 poly(arylene ether), aminohydroquinoline, and triethylaluminum
 (synthesis and characterization of novel
 tris(8-hydroxyquinoline)aluminum-containing poly(arylene ether))
 RN 97-93-8 HCAPLUS
 CN Aluminum, triethyl- (CA INDEX NAME)



RN 148-24-3 HCAPLUS
 CN 8-Quinolinol (CA INDEX NAME)



CC 35-5 (Chemistry of Synthetic High Polymers)
 Section cross-reference(s): 73, 76
 ST hydroxyquinoline aluminum polyarylene polyether prepn property;
 light emitting diode hydroxyquinoline aluminum
 polyarylene polyether
 IT Electroluminescent devices
 Glass transition temperature
 Luminescence
 Polymerization
 Solubility
 (synthesis and characterization of novel
 tris(8-hydroxyquinoline)aluminum-containing poly(arylene ether))
 IT 97-93-8DP, Triethylaluminum, reaction products with
 poly(arylene ether), aminohydroquinoline, and hydroxyquinoline
 148-24-3DP, 8-Hydroxyquinoline, reaction products with
 poly(arylene ether), aminohydroquinoline, and triethylaluminum
 21302-43-2DP, 5-Amino-8-hydroxyquinoline dihydrochloride, reaction
 products with poly(arylene ether), complexes with aluminum and
 hydroquinoline 294212-77-4DP, reaction products with
 aminohydroquinoline, complexes with aluminum and hydroquinoline
 (synthesis and characterization of novel
 tris(8-hydroxyquinoline)aluminum-containing poly(arylene ether))
 OS.CITING REF COUNT: 40 THERE ARE 40 CAPLUS RECORDS THAT CITE THIS
 RECORD (40 CITINGS)
 REFERENCE COUNT: 15 THERE ARE 15 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 36 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN
 ACCESSION NUMBER: 1999:350782 HCAPLUS Full-text
 DOCUMENT NUMBER: 130:359585
 TITLE: Low pressure vapor phase deposition of organic
 thin films
 INVENTOR(S): Forrest, Stephen R.; Burrows, Paul; Ban, Vladimir
 S.
 PATENT ASSIGNEE(S): The Trustees of Princeton University, USA
 SOURCE: PCT Int. Appl., 42 pp.
 CODEN: PIXXD2
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
WO 9925894	A1	19990527	WO 1998-US24424	19981116

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W: AL, AM, AT, AU, AZ, BA, BB, BG, BR, BY, CA, CH, CN, CU, CZ,
 DE, DK, EE, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IS,
 JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MD, MG,
 MK, MN, MW, MX, NO, NZ, PL, PT, RO, RU, SD, SE, SG, SI, SK,
 SL, TJ, TM, TR, TT, UA, UG, UZ, VN, YU, ZW

10/594,762

RW: GH, GM, KE, LS, MW, SD, SZ, UG, ZW, AT, BE, CH, CY, DE, DK,
 ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE, BF, BJ, CF,
 CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG

US 6337102	B1	20020108	US 1997-972156	19971117
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AU 9914124	A	19990607	AU 1999-14124	19981116
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EP 1032722	A1	20000906	EP 1998-957997	19981116
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EP 1032722	B1	20041027		
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JP 2001523768	T	20011127	JP 2000-521253	19981116
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TW 575699	B	20040211	TW 1998-87118943	19981117
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US 20010002279	A1	20010531	US 2000-736090	20001213
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US 20020155230	A1	20021024	US 2002-125400	20020419
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US 6558736	B2	20030506		
US 20040007178	A1	20040115	US 2003-427933	20030502
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US 20070131172	A1	20070614	US 2007-655258	20070119
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JP 2009238756	A	20091015	JP 2009-138382	20090609
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PRIORITY APPLN. INFO.:			US 1997-972156	A 19971117
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			WO 1998-US24424	W 19981116
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			US 2000-663143	B1 20000915
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			US 2000-736090	A1 20001213
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			US 2002-125400	A3 20020419
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			US 2003-427933	A1 20030502
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ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

ED Entered STN: 08 Jun 1999

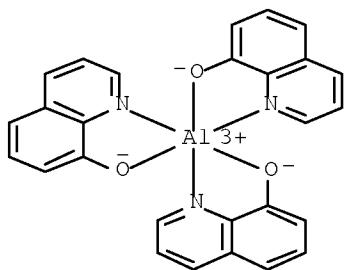
AB Methods for preparing organic thin films on substrates are described which entail providing a plurality of organic precursors in the vapor phase, and reacting the plurality of organic precursors at a pressure below atmospheric pressure to produce a film on the substrate. The methods may be applied to the production of organic ~~light-emitting~~ devices. Apparatus for carrying out the methods is described which comprises a ~~reaction chamber~~; means for heating the ~~reaction chamber~~; means for introducing vapors of organic precursor materials into the ~~reaction chamber~~; and means for reducing the pressure in the ~~reaction chamber~~ to below atmospheric pressure. Apparatus is also described which includes a plurality of vacuum chambers and a conveyor for moving substrates between them. Films, including ~~light-emitting~~ and nonlinear optical material films, formed by the methods are also claimed.

IT 2085-33-8P, Tris(8-hydroxyquinolinato)aluminum
 224785-36-8P

(methods for low pressure vapor phase deposition of organic thin films and deposition apparatus and films produced by the methods)

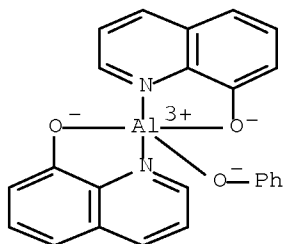
RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato- κ N1, κ O8)- (CA INDEX NAME)



RN 224785-36-8 HCAPLUS

CN Aluminum, phenoxybis(8-quinolinolato- κ N1, κ O8)- (CA INDEX NAME)



IC ICM C23C016-00

ICS H01J001-62

CC 75-1 (Crystallography and Liquid Crystals)

Section cross-reference(s): 73, 76

ST low pressure org vapor deposition app; ~~electroluminescent~~
device fabrication low pressure org vapor deposition; nonlinear
optical film low pressure org vapor deposition; light
~~emitting~~ film low pressure org vapor deposition

IT Phosphors

(~~electroluminescent~~; methods and apparatus for low pressure
vapor phase deposition of organic)

IT Electroluminescent devices

Electroluminescent devices

Semiconductor device fabrication

(methods and. apparatus for low pressure vapor phase deposition of organic
thin films for)

IT 917-23-7P, 5,10,15,20-Tetraphenyl-21H,23H-porphine

2085-33-8P, Tris(8-hydroxyquinolinato)aluminum 51325-91-8P,

4-(Dicyanomethylene)-2-methyl-6-(p-dimethylaminostyryl)-4H-pyran

65181-78-4P, N,N'-Diphenyl-N,N'-bis(3-methylphenyl)-1,1'-biphenyl-4,4'-

diamine 123847-85-8P 124729-98-2P, MTDATA 224785-36-8P

(methods for low pressure vapor phase deposition of organic thin films
and deposition apparatus and films produced by the methods)

OS.CITING REF COUNT: 65 THERE ARE 65 CAPLUS RECORDS THAT CITE THIS
RECORD (71 CITINGS)

REFERENCE COUNT: 9 THERE ARE 9 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L62 ANSWER 37 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 1997:756184 HCAPLUS Full-text

DOCUMENT NUMBER: 128:94828

ORIGINAL REFERENCE NO.: 128:18425a,18428a

TITLE: Low pressure organic vapor phase deposition of small molecular weight organic light emitting device structures

AUTHOR(S): Baldo, M. A.; Kozlov, V. G.; Burrows, P. E.; Forrest, S. R.; Ban, V. S.; Koene, B.; Thompson, M. E.

CORPORATE SOURCE: Princeton Materials Institute, Center for Photonics and Optoelectronic Materials, Department of Electrical Engineering, Princeton University, Princeton, NJ, 08544, USA

SOURCE: Applied Physics Letters (1997), 71(21), 3033-3035

CODEN: APPLAB; ISSN: 0003-6951

PUBLISHER: American Institute of Physics

DOCUMENT TYPE: Journal

LANGUAGE: English

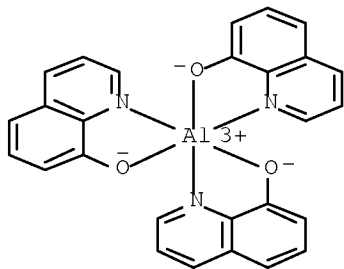
ED Entered STN: 04 Dec 1997

AB A new technique for the deposition of amorphous organic thin films, low pressure organic vapor phase deposition (LP-OVPD), was used to fabricate organic light emitting devices (OLEDs) consisting of a film of aluminum tris-(8 hydroxyquinoline) (Alq3) grown on the surface of a film of N'-diphenyl-N,N'-bis(3-methylphenyl)1-1'biphenyl-4-4'diamine. The resulting heterojunction OLED has a performance similar to conventional, small mol. weight OLEDs grown using thermal evaporation in vacuum. The LP-OVPD grown device has an external quantum efficiency of 0.40 ± 0.05 and a turn-on voltage of .apprx.6 V. The rapid throughput demonstrated with LP-OVPD has the potential to facilitate low cost mass production of conventional small mol. based OLEDs, and its use of low vacuum in a horizontal reactor lends itself to roll-to-roll deposition of organic films for many photonic device applications. The OLEDs were grown on both glass and flexible polyester substrates precoated with transparent layers of indium tin oxide (ITO). The cathode material was Mg:Ag alloy (25:1).

IT 2085-33-8, Tris(8-quinolinolato)aluminum
(organic light emitting device using low pressure organic vapor phase deposition)

RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato-κN1,κO8)- (CA INDEX NAME)



CC 73-5 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
 Section cross-reference(s): 76

ST ~~electroluminescent~~ device org vapor phase deposition;
 aluminum quinolinolato low pressure vapor deposition

IT Surface roughness
 (of organic light emitting device by low pressure
 organic vapor phase deposition using AFM)

IT Electric current-potential relationship
 (of organic light emitting device using low
 pressure organic vapor phase deposition)

IT Vapor phase epitaxy
 (organic light emitting device by low pressure
 organic vapor phase deposition)

IT ~~Electroluminescent~~ devices
 (organic light emitting device using low pressure
 organic vapor phase deposition)

IT Polyesters, uses
 (substrate; organic light emitting device using
 low pressure organic vapor phase deposition)

IT ~~2085-33-8~~, Tris(8-quinolinolato)aluminum 65181-78-4, TPD
 (organic light emitting device using low pressure
 organic vapor phase deposition)

OS.CITING REF COUNT: 28 THERE ARE 28 CAPLUS RECORDS THAT CITE THIS
 RECORD (28 CITINGS)

REFERENCE COUNT: 8 THERE ARE 8 CITED REFERENCES AVAILABLE FOR
 THIS RECORD. ALL CITATIONS AVAILABLE IN THE
 RE FORMAT

L62 ANSWER 38 OF 38 HCAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 1995:547736 HCAPLUS Full-text

DOCUMENT NUMBER: 123:69921

ORIGINAL REFERENCE NO.: 123:12237a,12240a

TITLE: Manufacture of organic ~~electroluminescent~~
 device

INVENTOR(S): Sato, Yoshiharu; Kanai, Hiroyuki

PATENT ASSIGNEE(S): Mitsubishi Kagaku KK, Japan

SOURCE: Jpn. Kokai Tokkyo Koho, 8 pp.
 CODEN: JKXXAF

DOCUMENT TYPE: Patent

LANGUAGE: Japanese

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
-----	----	-----	-----	-----
JP 07062526	A	19950307	JP 1993-205375	19930819
			<--	
PRIORITY APPLN. INFO.:			JP 1993-205375	19930819
			<--	

ED Entered STN: 13 May 1995

AB The device is manufactured by forming the organic light- emitting layer on a
 substrate at 60-150°. The layer may contain a metal complex of 8-
 hydroxyquinoline, which may be formed by vacuum vapor deposition. The device
 shows good heat resistance and emission stability for long periods.

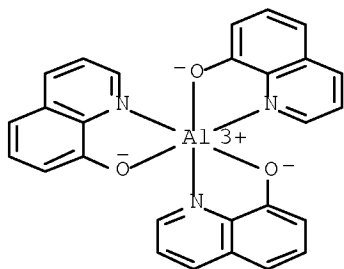
IT ~~2085-33-8~~, Tris(8-hydroxyquinolinato)aluminum
~~7069-05-8~~ 13978-85-3,
 Bis(8-hydroxyquinolinato)zinc 14642-34-3,
 Tris(8-hydroxyquinolinato)gallium

10/594,762

(manufacture of electroluminescent device containing
hydroxyquinoline metal complex)

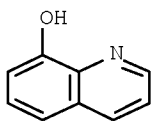
RN 2085-33-8 HCAPLUS

CN Aluminum, tris(8-quinolinolato- κ N1, κ O8)- (CA INDEX NAME)



RN 7069-05-8 HCAPLUS

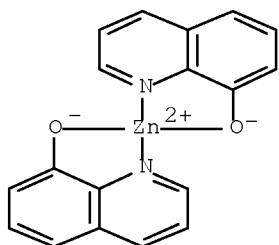
CN 8-Quinolinol, calcium salt (2:1) (CA INDEX NAME)



● 1/2 Ca

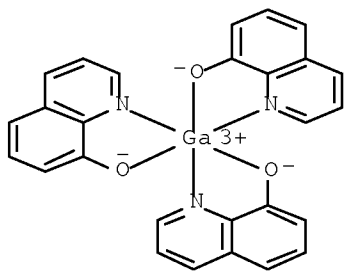
RN 13978-85-3 HCAPLUS

CN Zinc, bis(8-quinolinolato- κ N1, κ O8)-, (T-4)- (CA INDEX NAME)



RN 14642-34-3 HCAPLUS

CN Gallium, tris(8-quinolinolato- κ N1, κ O8)- (9CI) (CA INDEX NAME)



IC ICM C23C014-24
ICS C09K011-06; H05B033-10; H05B033-14

CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)

ST **electroluminescent** device hydroxyquinoline metal complex;
deposition vacuum vapor **electroluminescent** film

IT **Electroluminescent** devices
Vapor deposition processes
(manufacture of **electroluminescent** device containing
hydroxyquinoline metal complex)

IT 2085-33-8, Tris(8-hydroxyquinolinato)aluminum
7069-05-8 13978-85-3,
Bis(8-hydroxyquinolinato)zinc 14514-42-2,
Tris(8-hydroxyquinolinato)indium 14642-34-3,
Tris(8-hydroxyquinolinato)gallium 15276-55-8 15956-38-4,
Tris(8-hydroxyquinolinato)scandium 16009-78-2,
Tris(8-hydroxyquinolinato)yttrium 67952-28-7,
Bis(8-hydroxyquinolinato)magnesium
(manufacture of **electroluminescent** device containing
hydroxyquinoline metal complex)

OS.CITING REF COUNT: 1 THERE ARE 1 CAPLUS RECORDS THAT CITE THIS
RECORD (1 CITINGS)

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FILE 'HCAPLUS' ENTERED AT 07:40:51 ON 02 MAR 2010

L1 1 SEA SPE=ON ABB=ON PLU=ON US20070190247/PN
SEL RN

FILE 'REGISTRY' ENTERED AT 07:41:03 ON 02 MAR 2010

L2 20 SEA SPE=ON ABB=ON PLU=ON (1333-74-0/BI OR 15318-08-8/BI
OR 19553-62-9/BI OR 20791-15-5/BI OR 310888-77-8/BI OR
310888-80-3/BI OR 310888-81-4/BI OR 310888-82-5/BI OR
310888-85-8/BI OR 310888-87-0/BI OR 7358-26-1/BI OR
7440-37-1/BI OR 7440-59-7/BI OR 75-24-1/BI OR 7727-37-9/BI
OR 870126-56-0/BI OR 870126-57-1/BI OR 870126-58-2/BI OR
870126-59-3/BI OR 97-93-8/BI)
E 8-HYDROXYQUINOLINATE/CN
L3 1 SEA SPE=ON ABB=ON PLU=ON 8-HYDROXYQUINOLINATE/CN
E 8-HYDROXYQUINOLINE/CN
L4 1 SEA SPE=ON ABB=ON PLU=ON 8-HYDROXYQUINOLINE/CN
L5 685 SEA SPE=ON ABB=ON PLU=ON 148-24-3/CRN
L6 7 SEA SPE=ON ABB=ON PLU=ON L5 AND (AL OR GA OR ZN)/ELS
L7 16 SEA SPE=ON ABB=ON PLU=ON L2 AND M/ELS
L8 663827 SEA SPE=ON ABB=ON PLU=ON (AL OR GA OR ZN)/ELS
L9 122525 SEA SPE=ON ABB=ON PLU=ON L8 AND CCS/CI
L10 541302 SEA SPE=ON ABB=ON PLU=ON L8 NOT L9
L11 541302 SEA SPE=ON ABB=ON PLU=ON L10 OR L10
D 300000 RN
L12 300000 SEA RAN=(173351-91-2) SPE=ON ABB=ON PLU=ON L10 OR L10
L13 241302 SEA SPE=ON ABB=ON PLU=ON L11 NOT L12

FILE 'HCAPLUS' ENTERED AT 08:07:19 ON 02 MAR 2010

L14 23243 SEA SPE=ON ABB=ON PLU=ON L7
L15 143187 SEA SPE=ON ABB=ON PLU=ON L9
L16 140299 SEA SPE=ON ABB=ON PLU=ON L12
L17 2254991 SEA SPE=ON ABB=ON PLU=ON L13

FILE 'REGISTRY' ENTERED AT 08:23:38 ON 02 MAR 2010

L18 33 SEA SPE=ON ABB=ON PLU=ON L8 AND HYDROXYQUINOL?
L19 9 SEA SPE=ON ABB=ON PLU=ON 16582-16-4/CRN
L20 1 SEA SPE=ON ABB=ON PLU=ON L19 AND (AL OR GA OR ZN)/ELS

FILE 'HCAPLUS' ENTERED AT 08:24:42 ON 02 MAR 2010

L21 30 SEA SPE=ON ABB=ON PLU=ON L3
L22 10121 SEA SPE=ON ABB=ON PLU=ON L4
L23 1836 SEA SPE=ON ABB=ON PLU=ON L5
L24 9 SEA SPE=ON ABB=ON PLU=ON L19
L25 6 SEA SPE=ON ABB=ON PLU=ON L6
L26 9679 SEA SPE=ON ABB=ON PLU=ON L18
L27 1 SEA SPE=ON ABB=ON PLU=ON L20
L28 11763 SEA SPE=ON ABB=ON PLU=ON (L14 OR L15 OR L16 OR L17) AND
(L21 OR L22 OR L23 OR L24 OR L25 OR L26 OR L27)
L29 QUE SPE=ON ABB=ON PLU=ON LUM!N? OR ELECTROLUM!N? OR
ORGANOLUM!N? OR (ELECTRO OR ORGANO OR ORG#)(2A)LUM!N? OR
LIGHT?(2A)(EMIT? OR EMISSION?) OR EL OR E(W)L OR L(W)E(W)D
OR OLED OR LED
L30 8689 SEA SPE=ON ABB=ON PLU=ON L28 AND L29
L31 2171 SEA SPE=ON ABB=ON PLU=ON L30 AND PROC/RL

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E VAPOR DEPOSITION PROCESS/CT
L32      246823 SEA SPE=ON  ABB=ON  PLU=ON  "VAPOR DEPOSITION PROCESS"+PFT,
          NT/CT
L33      251 SEA SPE=ON  ABB=ON  PLU=ON  L31 AND L32
L34      12 SEA SPE=ON  ABB=ON  PLU=ON  L33 AND (L21 OR L22 OR L23)
L35      414 SEA SPE=ON  ABB=ON  PLU=ON  L30 AND (L21 OR L22 OR L23)
L36      89 SEA SPE=ON  ABB=ON  PLU=ON  L35 AND L31
L37      12 SEA SPE=ON  ABB=ON  PLU=ON  L36 AND CPS/RL
L38      11 SEA SPE=ON  ABB=ON  PLU=ON  L36 AND (VAPOR DEPOSIT? OR
          VAPOUR DEPOSIT?)
L39      23 SEA SPE=ON  ABB=ON  PLU=ON  L34 OR (L37 OR L38)
L40      QUE SPE=ON  ABB=ON  PLU=ON  REACTOR# OR (REACTION#) (2A)
          (VESSEL# OR CHAMBER# OR TANK# OR SYSTEM# OR SPACE# OR
          COMPARTMENT# OR RECEPTACLE# OR PORTION# OR PORT# OR
          ASSEMBLY# OR SUB#(W)ASSEMBLY#)
L41      1 SEA SPE=ON  ABB=ON  PLU=ON  L36 AND L40
L42      7 SEA SPE=ON  ABB=ON  PLU=ON  L31 AND L40
L43      29 SEA SPE=ON  ABB=ON  PLU=ON  L39 OR L41 OR L42
L44      20 SEA SPE=ON  ABB=ON  PLU=ON  L43 AND (1840-2006)/PRY,AY,PY
L45      258 SEA SPE=ON  ABB=ON  PLU=ON  L30 AND (L21 OR L22)
L46      13 SEA SPE=ON  ABB=ON  PLU=ON  L45 AND L32
L47      3 SEA SPE=ON  ABB=ON  PLU=ON  L45 AND L40
L48      71 SEA SPE=ON  ABB=ON  PLU=ON  L45 AND (FEED? OR DELIVER? OR
          SUPPLY? OR DISTRIBUT? OR TRANSPORT?)
L49      58 SEA SPE=ON  ABB=ON  PLU=ON  L48 AND OPTIC?/SC,SX
L50      49 SEA SPE=ON  ABB=ON  PLU=ON  L49 AND (1840-2006)/PRY,AY,PY
L51      65 SEA SPE=ON  ABB=ON  PLU=ON  L44 OR L50
L52      5 SEA SPE=ON  ABB=ON  PLU=ON  L51 AND L14
L53      QUE SPE=ON  ABB=ON  PLU=ON  FILM? OR THINFILM? OR LAYER?
          OR OVERLAY? OR OVERLAID? OR LAMIN? OR LAMEL? OR (MULTILAYER
          ?) OR SHEET? OR LEAF? OR FOIL? OR COAT? OR TOPCOAT? OR
          OVERCOAT? OR VENEER? OR SHEATH? OR COVER? OR ENVELOP? OR
          ENCAS? OR ENWRAP? OR OVERSPREAD?
L54      50 SEA SPE=ON  ABB=ON  PLU=ON  L51 AND L53
L55      49 SEA SPE=ON  ABB=ON  PLU=ON  L7 AND (L21 OR L22 OR L23)
L56      10 SEA SPE=ON  ABB=ON  PLU=ON  L55 AND L29 AND L53
L57      21 SEA SPE=ON  ABB=ON  PLU=ON  L55 AND L29
L58      21 SEA SPE=ON  ABB=ON  PLU=ON  L56 OR L57
L59      18 SEA SPE=ON  ABB=ON  PLU=ON  L58 AND (1840-2006)/PRY,AY,PY
L60      38 SEA SPE=ON  ABB=ON  PLU=ON  L44 OR L59
L61      9 SEA SPE=ON  ABB=ON  PLU=ON  L60 AND L50
L62      38 SEA SPE=ON  ABB=ON  PLU=ON  (L60 OR L61)

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